



Embedded Multimedia Card (eMMC 5.1 HS400)

**XT28EG16GA4YJECGA
XT28EG32GA4YJECGA**

**Specification
Version 1.3**

XTX Technology Inc.



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Revision History

Revision	Date	History
V1.0	2022/5	First Version
V1.1	2022/7	Update some typos
V1.2	2023/5	Add CID, CSD Extended register table
V1.3	2025/2	Update package connections



Product Overview

- Packaged NAND flash memory with eMMC 5.1 interface
- Compliant with eMMC Specification Ver.4.4, 4.41,4.5,5.0,5.1
- Bus mode
 - High-speed eMMC protocol
 - Clock frequency: 0-200MHz.
 - 12-wire bus (clock, DS, 1-bit command line, and 8-bit data bus) and a hardware reset.
- Supports three different data bus widths: 1 bit(default), 4 bits, 8 bits
 - Data transfer rate: up to 52Mbyte/s (using 8 parallel data lines at 52 MHz)
 - Single data rate: up to 200Mbyte/s @ 200MHz
 - Dual data rate: up to 400Mbyte/s @ 200MHz
- Operating voltage range:
 - VCCQ = 1.8V/3.3V
 - VCC = 3.3 V
- Error-free memory access
 - Internal error correction code (ECC) to protect data communication
 - Internal enhanced data management algorithm
 - Solid protection against sudden power failure safe-update operations for data content
- Security
 - Support secure bad block erase commands
 - Enhanced write Protection with permanent and partial protection options
- Quality
 - RoHS compliant (for detailed RoHS declaration, please contact your XTX representative.)
- Supports Field Firmware Update (FFU)
- Enhanced Device Lifetime
- Support Pre-EOL information
- Optimal Size
- Supports Production State Awareness
- Supports Power Off Notification for Sleep
- Supports HS400



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1. Introduction

XTX eMMC products follow the JEDEC eMMC 5.1 standard. It is an ideal universal storage solution for many electronic devices, including smartphones, tablets, PDAs, eBook readers, digital cameras, recorders, MP3, and MP4 players, electronic learning products, digital TVs, and set-top boxes. eMMC encloses the TLC NAND and eMMC controller inside as one JEDEC standard package, providing a standard interface to the host. The eMMC controller directly manages NAND flash, including ECC, wear-leveling, IOPS optimization, and read sensing.

Table 1-1 Device Summary

Product Part Number	NAND Density	Package	Operating voltage
XT28EG16GA4YJECGA	16GB	FBGA153	$V_{CC}=3.3V, V_{CCQ}=3.3/1.8 V$
XT28EG32GA4YJECGA	32GB		

2. Specification

2.1. System Performance

Table 2-1 Read/Write Performance

Products	Typical value			
	Read Sequential (MB/s)	Write Sequential (MB/s)	Random Write (IOPS)	Random Read (IOPS)
XT28EG16GA4YJECGA	307	135	16700	10100
XT28EG32GA4YJECGA	307	135	16700	10100

Note 1: Values given for an 8-bit bus width, running HS400 mode from XTX proprietary tool, $V_{CC}=3.3V, V_{CCQ}=1.8V$.

Note 2: Performance numbers might be subject to changes without notice

2.2. Power Consumption

Table 2-2 Device Power Consumption

	Read(mA)		Write(mA)		Standby(uA)	
	V_{CCQ} (1.8V)	V_{CC} (3.3V)	V_{CCQ} (1.8V)	V_{CC} (3.3V)	V_{CCQ}	V_{CC}
XT28EG16GA4YJECGA	100	102	47	72	55	40
XT28EG32GA4YJECGA	100	102	47	72	55	40

Note 1: Values given for an 8-bit bus width, a clock frequency of 200MHz DDR mode, $V_{CC}= 3.3V\pm 5\%, V_{CCQ}=1.8V\pm 5\%$

Note 2: Standby current is measured at $V_{CC}=3.3V\pm 5\%$, 8-bit bus width without clock frequency.

Note 3: Current numbers might be subject to changes without notice.

Note 4: The measurement for max RMS current is done as average RMS current consumption throughout 100ms.



2.3. Capacity according to Partition

Capacity	Boot partition 1	Boot partition 2	RPMB
16GB	4096 KB	4096 KB	4096 KB
32GB	4096 KB	4096 KB	4096 KB

2.4. User Density

Total user density depends on device type.

For example, 16 MB in the SLC mode requires 48 MB in TLC. This results in decreasing.

Device	User Density
16 GB	15,703,474,176 bytes
32 GB	31,331,450,880 bytes

3. eMMC Device and System

3.1. eMMC System Overview

The *eMMC* specification covers the behavior of the interface and the Device controller. As part of this specification, the existence of a host controller and a memory storage array are implied but the operation of these pieces is not fully specified.

XTX NAND Device consists of a single chip MMC controller and NAND flash memory module. The micro-controller interfaces with a host system allowing data to be written to and read from the NAND flash memory module. The controller allows the host to be independent of details of erasing and programming the flash memory.

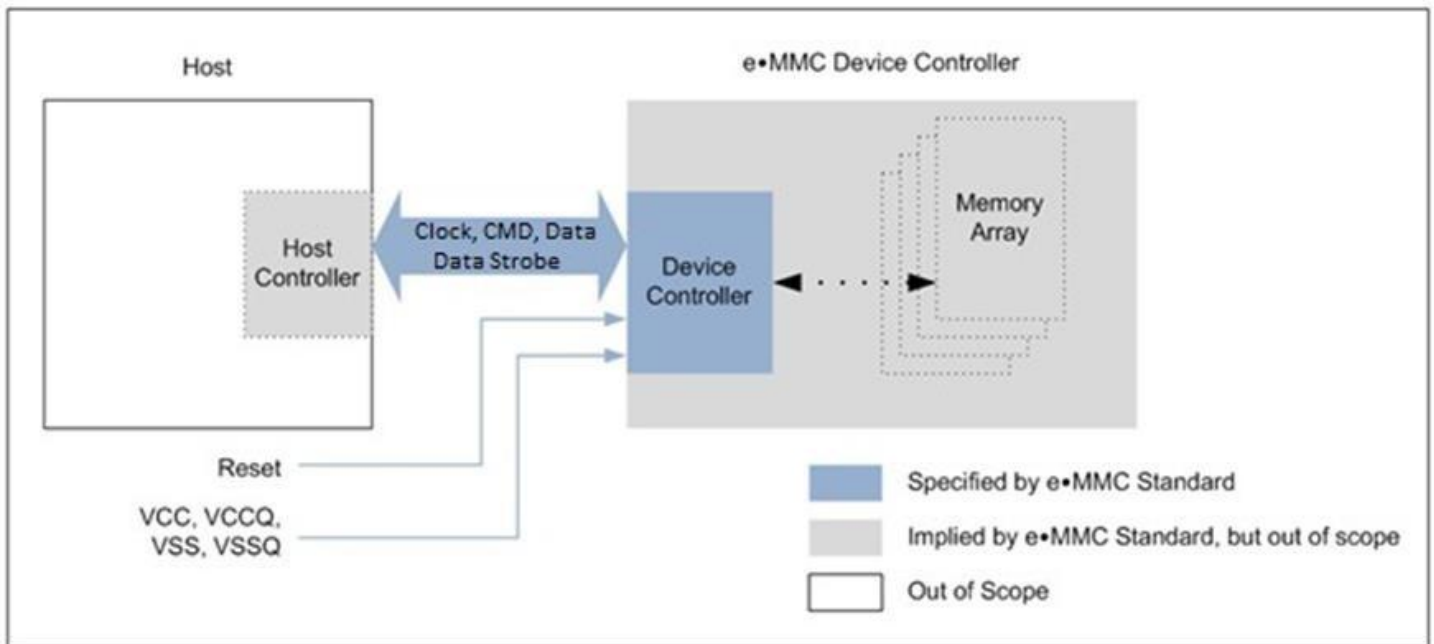


Figure 3-1 *eMMC* System Overview

3.2. Memory Addressing

Previous implementations of the *eMMC* specification follow byte addressing with a 32-bit field. This addressing mechanism permitted for *eMMC* densities up to and including 2 GB.

To support larger densities the addressing mechanism was updated to support sector addresses (512 B sectors). The sector addresses shall be used for all devices with a capacity larger than 2 GB.

To determine the addressing mode used the host should read bit [30:29] in the OCR register.



3.3. eMMC Device Overview

The *eMMC* device transfers data via a configurable number of data bus signals. The communication signals are:

3.3.1 Clock (CLK)

Each cycle of this signal directs a one-bit transfer on the command and either a one-bit (1x) or a two-bit transfer (2x) on all the data lines. The frequency may vary between zero and the maximum clock frequency.

3.3.2 Data Strobe (DS)

This signal is generated by the device and used for output in HS400 mode. The frequency of this signal follows the frequency of CLK. For data output, each cycle of this signal directs two bits transfer(2x) on the data - one bit for positive edge and the other bit for negative edge. For CRC status response output and CMD response output (enabled only HS400 enhanced strobe mode), the CRC status is latched on the positive edge only and doesn't care about the negative edge.

3.3.3 Command (CMD)

This signal is a bidirectional command channel used for Device initialization and transfer of commands. The CMD signal has two operation modes: open-drain for initialization mode, and push-pull for fast command transfer. Commands are sent from the *eMMC* host controller to the *eMMC* Device and responses are sent from the Device to the host.

3.3.4 Input/Outputs (DAT0-DAT7)

These are bidirectional data channels. The DAT signals operate in push-pull mode. Only the Device or the host is driving these signals at a time. By default, after powering up or resetting, only DAT0 is used for data transfer. A wider data bus can be configured for data transfer, using either DAT0-DAT3 or DAT0-DAT7, by the *eMMC* host controller. The *eMMC* Device includes internal pull-ups for data lines DAT1-DAT7. Immediately after entering the 4-bit mode, the Device disconnects the internal pull-ups of lines DAT1, DAT2, and DAT3. Correspondingly, immediately after entering the 8-bit mode, the Device disconnects the internal pull-ups of lines DAT1–DAT7.

Table 3-1 Communication Interface

Name	Type ¹	Description
CLK	I	Clock
DAT0	I/O/PP	Data
DAT1	I/O/PP	Data
DAT2	I/O/PP	Data
DAT3	I/O/PP	Data
DAT4	I/O/PP	Data
DAT5	I/O/PP	Data
DAT6	I/O/PP	Data
DAT7	I/O/PP	Data
CMD	I/O/PP/OD	Command/Response
RST_n	I	Hardware reset
VCC	S	Supply voltage for Core
VCCQ	S	Supply voltage for I/O
VSS	S	Supply voltage ground for Core



VSSQ	S	Supply voltage ground for I/O
DS	O/PP	Data strobe
Note1 : I: input; O: output; PP: push-pull; OD: open-drain; NC: Not connected (or logical high); S: power supply.		

Table 3-2 eMMC Registers

Name	Width (Bytes)	Description	Implementation
CID	16	Device Identification number, an individual number for identification.	Mandatory
RCA	2	Relative Device Address is the Device system address, dynamically assigned by the host during initialization.	Mandatory
DSR	2	Driver Stage Register, to configure the Device's output drivers.	Optional
CSD	16	Device Specific Data, information about the Device operation conditions.	Mandatory
OCR	4	Operation Conditions Register. Used by a special broadcast command to identify the voltage type of the Device.	Mandatory
EXT_CSD	512	Extended Device Specific Data. Contains information about the Device's capabilities and selected modes. Introduced in standard v4.0	Mandatory

The host may reset the device by:

- Switching the power supply off and back on. The device shall have its power-on detection circuitry which puts the device into a defined state after the power-on Device.
- A reset signal
- By sending a special command

3.4. Bus Protocol

After a power-on reset, the host must initialize the device by a special message-based eMMC bus protocol. For more details, refer to section 5.3.1 of the JEDEC Standard Specification No. JESD84-B51.

3.5. Bus Speed Modes

eMMC defines several bus speed modes as shown in Table 3-3.

Table 3-3 Bus Speed Mode

Mode	Data Rate	IO Voltage	Bus Width	Frequency	Max Data Transfer (implies x8 bus width)
Backward Compatibility with legacy MMC card	Single	3.3/1.8V	1, 4, 8	0-26MHz	26MB/s
High-Speed SDR	Single	3.3/1.8V	4, 8	0-52MHz	52MB/s
High-Speed DDR	Dual	3.3/1.8V	4, 8	0-52MHz	104MB/s
HS200	Single	1.8V	4, 8	0-200MHz	200MB/s
HS400	Dual	1.8V	8	0-200MHz	400MB/s

3.5.1 HS200 Bus Speed Mode

The HS200 mode offers the following features:

- SDR Data sampling method
- CLK frequency up to 200MHz, Data rate up to 200MB/s
- 8-bit bus width supported
- Single-ended signaling with 4 selectable Drive Strength
- Signaling levels of 1.8V
- Tuning concept for Read Operations

3.5.2 HS200 System Block Diagram

Figure 3-2 shows a typical HS200 Host and Device system. The host has a clock generator, which supplies CLK to the Device. For write operations, clock and data direction are the same, write data can be transferred synchronously with CLK, regardless of transmission line delay. For read operations, clock and data direction are opposite; the read data received by the Host is delayed by round-trip delay, output delay, and latency of the Host and Device. For reads, the Host needs to have an adjustable sampling point to reliably receive the incoming data

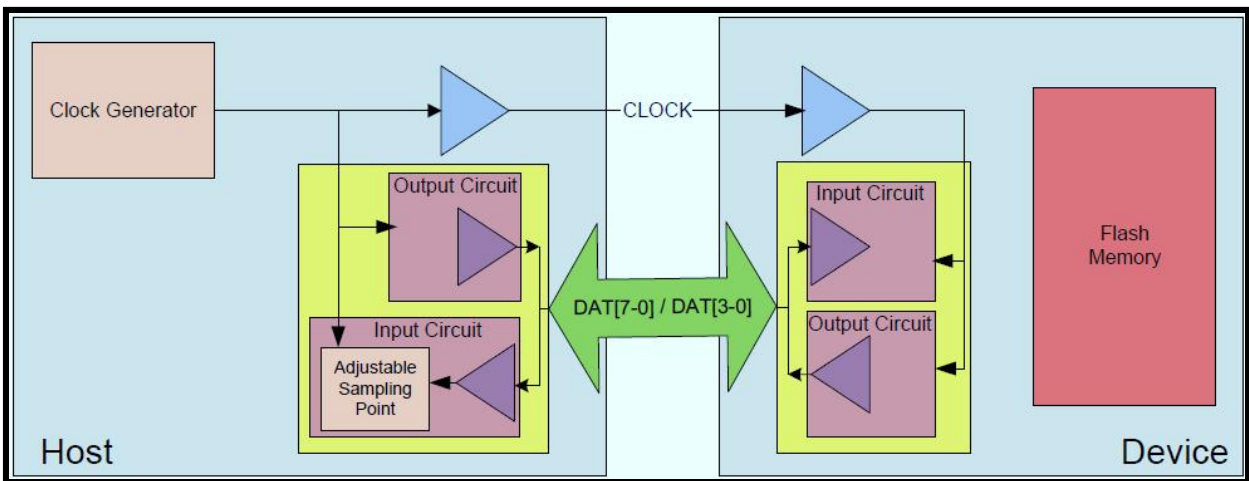


Figure 3-2 System Block Diagram

3.5.3 HS400 Bus Speed Mode

The HS400 mode has the following features

- DDR Data sampling method
- CLK frequency up to 200MHz, Data rate up to 400MB/s
- Only 8-bit bus width supported
- Signaling levels of 1.8V
- Support up to 5 selective Drive Strength
- Data strobe signal is toggled only for Data out and CRC response

3.5.4 HS400 System Block Diagram

Figure 3-3 shows a typical HS400 Host and Device system. The host has a clock generator, which supplies CLK to the Device. For read operations, the Data Strobe is generated by the device output circuit. The host receives the data which is aligned to the edge of the Data Strobe.

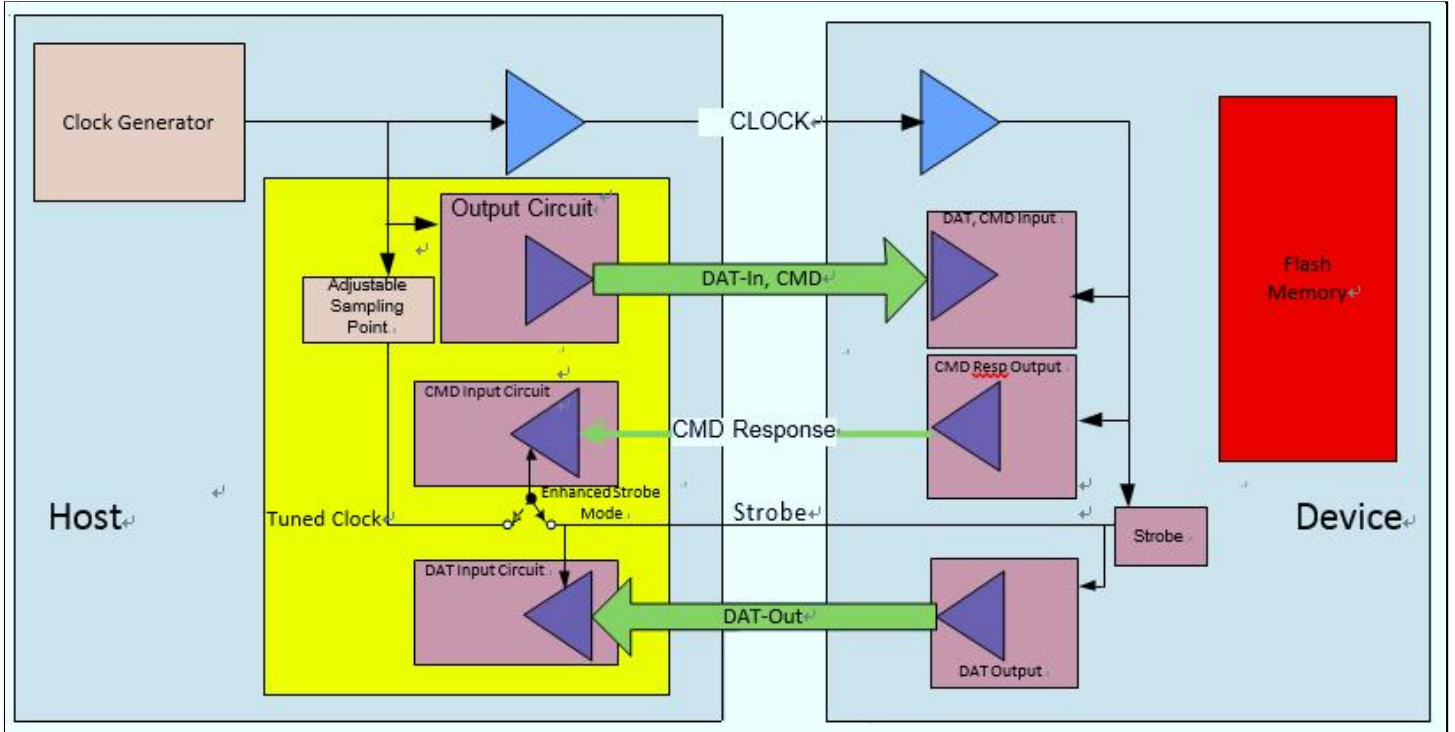


Figure 3-3 HS400 Host and Device block diagram



4. eMMC Functional Description

4.1 eMMC Overview

All communication between the host and device is controlled by the host (main chip). The host sends a command, which results in a device response. For more details, refer to section 6.1 of the JEDEC Standard Specification No. JESD84-B51.

Five operation modes are defined for the *eMMC* system:

- Boot operation mode
- Device identification mode
- Interrupt mode
- Data transfer mode
- Inactive mode

4.2 Boot Operation Mode

In boot operation mode, the master (*eMMC* host) can read boot data from the slave (*eMMC* device) by keeping the CMD line low or sending CMD0 with argument + 0xFFFFFFFF, before issuing CMD1. The data can be read from either the boot area or the user area depending on the register setting. For more details, refer to section 6.3 of the JEDEC Standard Specification No. JESD84-B51.

4.3 Device Identification Mode

While in device identification mode the host resets the device, validates operation voltage range and access mode, identifies the device, and assigns a Relative device Address (RCA) to the device on the bus. All data communication in the Device Identification Mode uses the command line (CMD) only. For more details, refer to section 6.4 of the JEDEC Standard Specification No. JESD84-B51.

4.4 Interrupt Mode

The interrupt mode on the *eMMC* system enables the master (*eMMC* host) to grant the transmission allowance to the slaves (Device) simultaneously. This mode reduces the polling load for the host and hence, the power consumption of the system, while maintaining adequate responsiveness of the host to a Device request for service. Supporting *eMMC* interrupt mode is an option both for the host and the Device. For more details, refer to section 6.5 of the JEDEC Standard Specification No. JESD84-B51.

4.5 Data Transfer Mode

When the Device is in *Stand-by* State, communication over the CMD and DAT lines will be performed in push-pull mode. For more details, refer to section 6.6 of the JEDEC Standard Specification No. JESD84-B51.

4.6 Inactive Mode

The device will enter inactive mode if either the device's operating voltage range or access mode is not valid. The device can also enter inactive mode with the GO_INACTIVE_STATE command (CMD15). The device will reset to a *Pre-idle* state with a power cycle. For more details, refer to section 6.1 of the JEDEC Standard Specification No. JESD84-B51.

4.7 H/W Reset Operation

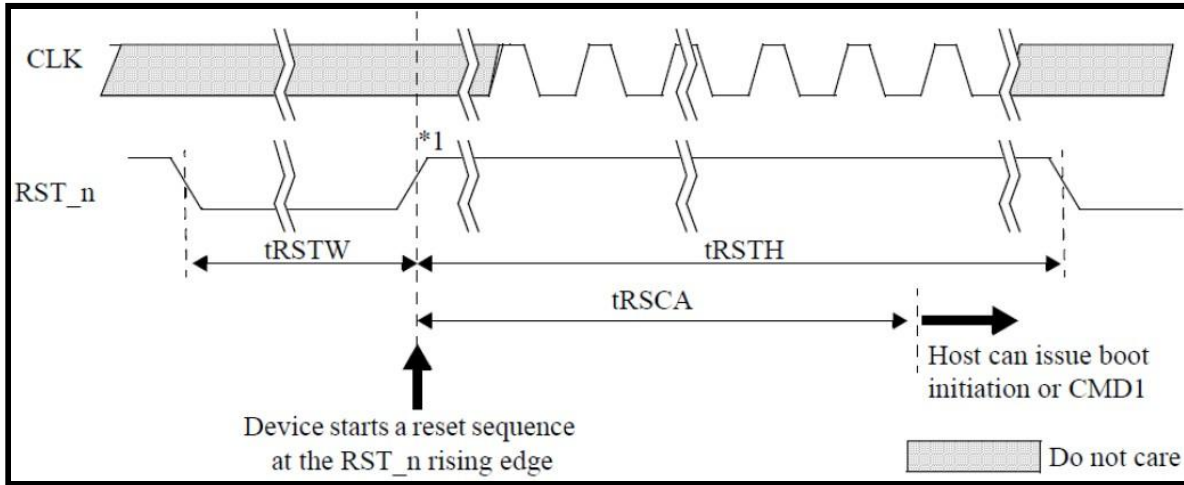


Figure 4-1 H/W Reset Waveform

Note1: The device will detect the rising edge of RST_n signal to trigger an internal reset sequence

Table 4-1 H/W Reset Timing Parameters

Symbol	Comment	Min	Max	Unit
tRSTW	RST_n pulse width	1		[us]
tRSCA	RST_n to Command time	200 ¹		[us]
tRSTH	RST_n high period (interval time)	1		[us]

Note1 : 74 cycles of clock signal required before issuing CMD1 or CMD0 with argument 0xFFFFFFFF

4.8 Noise Filtering Timing for H/W Reset

The device must filter out 5ns or less pulse width for noise immunity

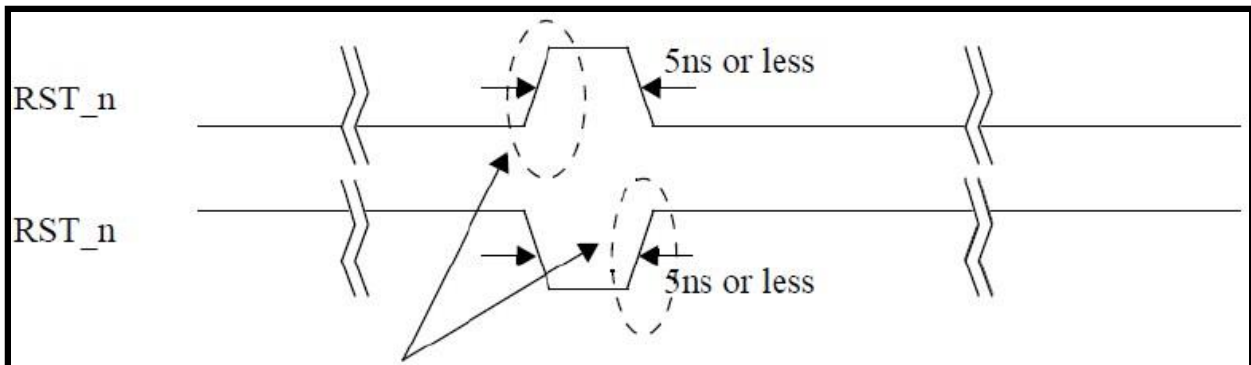


Figure 4-2 Noise Filtering Timing for H/W Reset

The device must not detect this rising edge.

The device must not detect 5ns or less of positive or negative RST_n pulse.

The device must detect more than or equal to 1us of positive or negative RST_n pulse width.



4.9 Field Firmware Update (FFU)

Field Firmware Updates (FFU) enable feature enhancement in the field. Using this mechanism the host downloads a new version of the firmware to the eMMC device and, following a successful download, instructs the eMMC device to install the new downloaded firmware into the device.

To start the FFU process the host first checks if the eMMC device supports FFU capabilities by reading `SUPPPORTED_MODES` and `FW_CONFIG` fields in the `EXT_CSD`. If the eMMC device supports the FFU feature the host may start the FFU process. The FFU process starts by switching to FFU Mode in the `MODE_CONFIG` field in the `EXT_CSD`. In FFU Mode host should use closed-ended or open-ended commands for downloading the new firmware and reading vendor proprietary data. In this mode, the host should set the argument of these commands to be as defined in the `FFU_ARG` field. In case these commands have a different argument, the device behavior is not defined and the FFU process may fail. The host should set Block Length to be `DATA_SECTOR_SIZE`. Downloaded firmware bundle must be `DATA_SECTOR_SIZE` size aligned (internal padding of the bundle might be required). Once in FFU Mode, the host may send the new firmware bundle to the device using one or more write commands.

The host could regain regular functionality of write and read commands by setting the `MODE_CONFIG` field in the `EXT_CSD` back to Normal state. Switching out of FFU Mode may abort the firmware download operation. When the host switched back to FFU Mode, the host should check the FFU Status to get an indication about the number of sectors that were downloaded successfully by reading the `NUMBER_OF_FW_SECTORS_CORRECTLY_PROGRAMMED` in the extended CSD. In case the number of sectors that were downloaded successfully is zero the host should re-start downloading the new firmware bundle from its first sector. In case the number of sectors that were downloaded successfully is positive the host should continue the download from the next sector, which would resume the firmware download operation.

In case the `MODE_OPERATION_CODES` field is not supported by the device the host sets to `NORMAL` state and initiates a `CMD0/HW_Reset/Power` cycle to install the new firmware. In such a case, the device doesn't need to use `NUMBER_OF_FW_SECTORS_CORRECTLY_PROGRAMMED`.

In both cases, the occurrence of a `CMD0/HW_Reset/Power` occurred before the host successfully downloaded the new firmware bundle to the device may cause the firmware download process to be aborted.



4.10 Power off Notification for sleep

The host should notify the device before it powers the device off. This allows the device to better prepare itself for being powered off. Powering the device off means to turn off all its power supplies. In particular, the host should issue a power-off notification (POWER_OFF_LONG, POWER_OFF_SHORT) if it intends to turn off both VCC and VCCQ power or it may use a power-off notification (SLEEP_NOTIFICATION) if it intends to turn-off VCC after moving the device to Sleep state.

To indicate to the device that power off notification is supported by the host, a supporting host shall first set the POWER_OFF_NOTIFICATION byte in EXT_CSD [34] to POWERED_ON (0x01). To execute a power off, before powering the device down the host will change the value to either POWER_OFF_SHORT (0x02) or POWER_OFF_LONG (0x03). The host should wait for the busy line to be de-asserted. Once the setting has changed to either 0x02 or 0x03, the host may safely power off the device.

The host may issue SLEEP_AWAKE (CMD5) to enter or exit from the Sleep state if the POWER_OFF_NOTIFICATION byte is set to POWERED_ON. Before moving to the Standby state and then to the Sleep state, the host sets POWER_OFF_NOTIFICATION to SLEEP_NOTIFICATION and waits for the DAT0 line de-assertion. While in Sleep (slp) state VCC (Memory supply) may be turned off as defined in 4.1.6. Removing power supplies other than VCC while the device is in the Sleep (slp) state may result in undefined device behavior. Before removing all power supplies, the host should transition the device out of the Sleep (slp) state back to the Transfer state using CMD5 and CMD7 and then execute a power-off notification setting POWER_OFF_NOTIFICATION byte to either POWER_OFF_SHORT or POWER_OFF_LONG.

If the host continues to send commands to the device after switching to the power-off setting (POWER_OFF_LONG, POWER_OFF_SHORT, or SLEEP_NOTIFICATION) or performs HPI during its busy condition, the device shall restore the POWER_OFF_NOTIFICATION byte to POWERED_ON.

If the host tries to change POWER_OFF_NOTIFICATION to 0x00 after writing another value there, a SWITCH_ERROR is generated.

The difference between the two power-off modes is how urgent the host wants to turn power-off. The device should respond to POWER_OFF_SHORT quickly under the generic CMD6 timeout. If more time is acceptable, POWER_OFF_LONG may be used and the device shall respond to it within the POWER_OFF_LONG_TIME timeout.

While POWER_OFF_NOTIFICATION is set to POWERED_ON, the device expects the host to host shall:

- Keep the device power supplies alive (both V_{CC} and V_{CCQ}) and in their active mode
- Do not power off the device intentionally before changing POWER_OFF_NOTIFICATION to either POWER_OFF_LONG or POWER_OFF_SHORT
- Not power off V_{CC} intentionally before changing POWER_OFF_NOTIFICATION to SLEEP_NOTIFICATION and before moving the device to Sleep state

Before moving to the Sleep state hosts may set the POWER_OFF_NOTIFICATION byte to SLEEP_NOTIFICATION (0x04) if aware that the device is capable of autonomously initiating background



operations for possible performance improvements. The host should wait for the busy line to be de-asserted. The busy line may be asserted up the period defined in SLEEP_NOTIFICATION_TIME byte in EXT_CSD [216]. Once the setting has changed to 0x04 host may set the device into Sleep mode (CMD7+CMD5). After getting out from Sleep the POWER_OFF_NOTIFICATION byte will restore its value to POWERED_ON. HPI may interrupt the SLEEP_NOTIFICATION operation. In that case, POWER_OFF_NOTIFICATION byte will restore to POWERED_ON.

4.11 Enhanced User Data Area

XTX eMMC supports Enhanced User Data Area feature which allows the User Data Area of eMMC to be configured as SLC Mode. Therefore, when the host sets the Enhanced User Data Area, the area will occupy double the size of the original setup size. The Max Enhanced User Data Area size is defined as - $(MAX_ENH_SIZE_MULT \times HC_WP_GRP_SIZE \times HC_ERASE_GRP_SIZE \times 512 \text{ Kbytes})$. The Enhanced use data area size is defined as - $(ENH_SIZE_MULT \times HC_WP_GRP_SIZE \times HC_ERASE_GRP_SIZE \times 512 \text{ Kbytes})$. The host shall follow the flow chart of JEDEC spec for configuring the parameters of General Purpose Area Partitions and Enhanced User Data Area.



5. Register Settings

Within the Device interface, six registers are defined: OCR, CID, CSD, EXT_CSD, RCA, and DSR. These can be accessed only by corresponding commands (see Section 6.10 of JESD84-B51).

5.1. OCR Register

The 32-bit operation conditions register (OCR) stores the VDD voltage profile of the Device and the access mode indication. In addition, this register includes a status information bit. This status bit is set if the Device power-up procedure has been finished. The OCR register shall be implemented by all Devices.

Table 5-1 OCR Register

OCR bit	VDD voltage window	Dual Voltage Value
[6:0]	Reserved	00 0000b
[7]	1.70 - 1.95V	1b
[14:8]	2.0-2.7V	000 0000b
[23:15]	2.7-3.6V	1 1111 1111b
[28:24]	Reserved	0 0000b
[30:29]	Access Mode	00b (byte mode) 10b (sector mode)
[31]	Device power-up status bit (busy) 1=ready ¹	

NOTES:

1. This bit is set to LOW if the Device has not finished the power-up routine.

5.2. CID Register

The Card Identification (CID) register is 128 bits wide. It contains the Device identification information used during the Device identification phase (*eMMC* protocol). For details, refer to JEDEC Standard Specification No. JESD84-B51.

Table 5-2 CID Register

CID Fields Name	Field	Width	CID slice	Value
Manufacturer ID	MID	8	[127:120]	0Bh
Reserved	-	6	[119:114]	0h
Device/BGA	CBX	2	[113:112]	1h
OEM/Application ID	OID	8	[111:104]	1h
Product name	PNM	48	[103:56]	16GB – 4D4D43313647h “MMC16G” 32GB – 4D4D43333247h “MMC32G”
Product revision	PRV	8	[55:48]	51h
Product serial number	PSN	32	[47:16]	Random by Production
Manufacturing date	MDT	8	[15:8]	Month, Year
CRC7 checksum	CRC	7	[7:1]	- (Note 1)
Reserved	-	1	[0:0]	1h

NOTES: The descriptions are the same as *eMMC*™ JEDEC standard.



5.3. CSD Register

The Card-Specific Data (CSD) register provides information on how to access the contents stored in *eMMC*. The CSD registers are used to define the error correction type, maximum data access time, data transfer speed, data format...etc. For details, refer to section 7.3 of the JEDEC Standard Specification No. JESD84-B51.

Table 5-3 CSD Register

Name	Field	Width	Cell Type	CSD-slice	Value
CSD structure	CSD_STRUCTURE	2	R	[127:126]	3h
System specification version	SPEC_VERS	4	R	[125:122]	4h
Reserved	-	2	R	[121:120]	0h
Data read access-time 1	TAAC	8	R	[119:112]	4Fh
Data read access-time 2 in CLK cycles (NSAC*100)	NSAC	8	R	[111:104]	1h
Max. bus clock frequency	TRAN_SPEED	8	R	[103:96]	32h
Device command classes	CCC	12	R	[95:84]	8F5h
Max. read data block length	READ_BL_LEN	4	R	[83:80]	9h
Partial blocks for read allowed	READ_BL_PARTIAL	1	R	[79:79]	0h
Write block misalignment	WRITE_BLK_MISALIGN	1	R	[78:78]	0h
Read block misalignment	READ_BLK_MISALIGN	1	R	[77:77]	0h
DSR implemented	DSR_IMP	1	R	[76:76]	0h
Reserved	-	2	R	[75:74]	0h
Device size	C_SIZE	12	R	[73:62]	FFFh
Max. read current @ VDD min	VDD_R_CURR_MIN	3	R	[61:59]	7h
Max. read current @ VDD max	VDD_R_CURR_MAX	3	R	[58:56]	7h
Max. write current @ VDD min	VDD_W_CURR_MIN	3	R	[55:53]	7h
Max. write current @ VDD max	VDD_W_CURR_MAX	3	R	[52:50]	7h
Device size multiplier	C_SIZE_MULT	3	R	[49:47]	7h
Erase group size	ERASE_GRP_SIZE	5	R	[46:42]	1Fh
Erase group size multiplier	ERASE_GRP_MULT	5	R	[41:37]	1Fh
Write protect group size	WP_GRP_SIZE	5	R	[36:32]	0Fh
Write protect group enable	WP_GRP_ENABLE	1	R	[31:31]	1h
Manufacturer default ECC	DEFAULT_ECC	2	R	[30:29]	0h
Write speed factor	R2W_FACTOR	3	R	[28:26]	2h
Max. write data block length	WRITE_BL_LEN	4	R	[25:22]	9h
Partial blocks for write allowed	WRITE_BL_PARTIAL	1	R	[21:21]	0h
Reserved	-	4	R	[20:17]	0h
Content protection application	CONTENT_PROT_APP	1	R	[16:16]	0h
File format group	FILE_FORMAT_GRP	1	R/W	[15:15]	0h
Copy flag (OTP)	COPY	1	R/W	[14:14]	0h
Permanent write protection	PERM_WRITE_PROTECT	1	R/W	[13:13]	0h
Temporary write protection	TMP_WRITE_PROTECT	1	R/W	[12:12]	0h
File format	FILE_FORMAT	2	R/W	[11:10]	0h
ECC code	ECC	2	R/W	[9:8]	0h
CRC	CRC	7	R/W	[7:1]	2Eh
Not used, always '1'	-	1	-	[0:0]	1h



5.4. Extended CSD Register

The Extended CSD register defines the Device properties and selected modes. It is 512 bytes long. The most significant 320 bytes are the Properties segment, which defines the Device capabilities and cannot be modified by the host. The lower 192 bytes are the Modes segment, which defines the configuration the Device is working in. These modes can be changed by the host using the SWITCH command. For details, refer to section 7.4 of the JEDEC Standard Specification No. JESD84-B51.

Table 5-4 Extended CSD Register

Name	Field	Size (Bytes)	CSD-slice	Value
Reserved	–	6	[511:506]	0h
Extended Security Commands Error	EXT_SECURITY_ERR	1	[505]	0h
Supported Command Sets	S_CMD_SET	1	[504]	1h
HPI features	HPI_FEATURES	1	[503]	1h
Background operations support	BKOPS_SUPPORT	1	[502]	1h
Max packed read commands	MAX_PACKED_READS	1	[501]	3Ch
Max packed write commands	MAX_PACKED_WRITES	1	[500]	20h
Data Tag Support	DATA_TAG_SUPPORT	1	[499]	1h
Tag Unit Size	TAG_UNIT_SIZE	1	[498]	3h
Tag Resources Size	TAG_RES_SIZE	1	[497]	0h
Context management capabilities	CONTEXT_CAPABILITIES	1	[496]	5h
Large Unit size	LARGE_UNIT_SIZE_M1	1	[495]	23h
Extended partitions attribute support	EXT_SUPPORT	1	[494]	3h
Supported modes	SUPPORTED_MODES	1	[493]	01h
FFU features	FFU_FEATURES	1	[492]	0h
Operation codes timeout	OPERATION_CODE_TIMEOUT	1	[491]	0h
FFU Argument	FFU_ARG	4	[490:487]	65535
Barrier support	BARRIER_SUPPORT	1	[486]	1h
Reserved	Reserved	177	[485:309]	–
CMDQ support	CMDQ_SUPPORT	1	[308]	1h
CMDQ depth	CMDQ_DEPTH	1	[307]	1Fh
Reserved	Reserved	1	[306]	0h
Number of FW sectors correctly programmed	NUMBER_OF_FW_SECTORS_CORRECTLY_PROGRAMMED	4	[305:302]	0h
Vendor proprietary health report	VENDOR_PROPRIETARY_HEALTH_REPORT	32	[301:270]	0h



Name	Field	Size (Bytes)	CSD-slice	Value
Device life time estimation type B	DEVICE_LIFE_TIME_EST_TYP_B	1	[269]	01h
Device life time estimation type A	DEVICE_LIFE_TIME_EST_TYP_A	1	[268]	01h
Pre EOL information	PRE_EOL_INFO	1	[267]	01h
Optimal read size	OPTIMAL_READ_SIZE	1	[266]	01h
Optimal write size	OPTIMAL_WRITE_SIZE	1	[265]	8h
Optimal trim unit size	OPTIMAL_TRIM_UNIT_SIZE	1	[264]	01h
Device version	DEVICE_VERSION	2	[263:262]	0h
Firmware version	FIRMWARE_VERSION	8	[261:254]	4h
Power class for 200MHz, DDR at VCC=3.6V	PWR_CL_DDR_200_360	1	[253]	0h
Cache size	CACHE_SIZE	4	[252:249]	768
Generic CMD6 timeout	GENERIC_CMD6_TIME	1	[248]	32h
Power off notification(long) timeout	POWER_OFF_LONG_TIME	1	[247]	FFh
Background operations status	BKOPS_STATUS	1	[246]	0h
Number of correctly programmed sectors	CORRECTLY_PRG_SECTORS_NUM	4	[245:242]	0h
1st initialization time after partitioning	INI_TIMEOUT_AP	1	[241]	64h
Cache Flushing Policy	CACHE_FLUSH_POLICY	1	[240]	1h
Power class for 52MHz, DDR at 3.6V	PWR_CL_DDR_52_360	1	[239]	0h
Power class for 52MHz, DDR at 1.95V	PWR_CL_DDR_52_195	1	[238]	0h
Power class for 200MHz at 3.6V	PWR_CL_200_195	1	[237]	0h
Power class for 200MHz, at 1.95V	PWR_CL_200_130	1	[236]	0h
Minimum Write Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_W_8_52	1	[235]	0h
Minimum Read Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_R_8_52	1	[234]	0h
Reserved	-	1	[233]	-
TRIM Multiplier	TRIM_MULT	1	[232]	11h
Secure Feature support	SEC_FEATURE_SUPPORT	1	[231]	55h
Secure Erase Multiplier	SEC_ERASE_MULT	1	[230]	F7h
Secure TRIM Multiplier	SEC_TRIM_MULT	1	[229]	F7h
Boot information	BOOT_INFO	1	[228]	7h
Reserved	-	1	[227]	-
Boot partition size	BOOT_SIZE_MULT	1	[226]	20h



Name	Field	Size (Bytes)	CSD-slice	Value
Access size	ACC_SIZE	1	[225]	8h
High-capacity erase unit size	HC_ERASE_GRP_SIZE	1	[224]	1h
High-capacity erase timeout	ERASE_TIMEOUT_MULT	1	[223]	11h
Reliable write sector count	REL_WR_SEC_C	1	[222]	1h
High-capacity write protect group size	HC_WP_GRP_SIZE	1	[221]	10h
Sleep current (VCC)	S_C_VCC	1	[220]	8h
Sleep current (VCCQ)	S_C_VCCQ	1	[219]	8h
Production state awareness Timeout	PRODUCTION_STATE_AWARENESS_TIMEOUT	1	[218]	14h
Sleep/awake timeout	S_A_TIMEOUT	1	[217]	15h
Sleep Notification timeout	SLEEP_NOTIFICATION_TIME	1	[216]	Fh
Sector Count	SEC_COUNT	4	[215:212]	16GB: 01D40000h 32GB: 03A5C000h
Security write protect information	SECURE_WP_INFO	1	[211]	1h
Minimum Write Performance for 8bit at 52MHz	MIN_PERF_W_8_52	1	[210]	8h
Minimum Read Performance for 8bit at 52MHz	MIN_PERF_R_8_52	1	[209]	8h
Minimum Write Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_W_8_26_4_52	1	[208]	8h
Minimum Read Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_R_8_26_4_52	1	[207]	8h
Minimum Write Performance for 4bit at 26MHz	MIN_PERF_W_4_26	1	[206]	8h
Minimum Read Performance for 4bit at 26MHz	MIN_PERF_R_4_26	1	[205]	8h
Reserved	-	1	[204]	-
Power class for 26MHz at 3.6V 1 R	PWR_CL_26_360	1	[203]	0h
Power class for 52MHz at 3.6V 1 R	PWR_CL_52_360	1	[202]	0h
Power class for 26MHz at 1.95V 1 R	PWR_CL_26_195	1	[201]	0h
Power class for 52MHz at 1.95V 1 R	PWR_CL_52_195	1	[200]	0h
Partition switching timing	PARTITION_SWITCH_TIME	1	[199]	6h
Out-of-interrupt busy timing	OUT_OF_INTERRUPT_TIME	1	[198]	FFh



Name	Field	Size (Bytes)	CSD-slice	Value
I/O Driver Strength	DRIVER_STRENGTH	1	[197]	1Fh
Device type	DEVICE_TYPE	1	[196]	57h
Reserved	–	1	[195]	-
CSD structure version	CSD_STRUCTURE	1	[194]	2h
Reserved	–	1	[193]	-
Extended CSD revision	EXT_CSD_REV	1	[192]	8h
Command set	CMD_SET	1	[191]	0h
Reserved	–	1	[190]	-
Command set revision	CMD_SET_REV	1	[189]	0h
Reserved	–	1	[188]	-
Power class	POWER_CLASS	1	[187]	0h
Reserved	–	1	[186]	=
High-speed interface timing	HS_TIMING	1	[185]	1h (note 3)
Strobe support	STROBE_SUPPORT	1	[184]	1h
Bus width mode	BUS_WIDTH	1	[183]	2h (note 4)
Reserved	–	1	[182]	-
Erased memory content	ERASED_MEM_CONT	1	[181]	0h
Reserved	–	1	[180]	-
Partition configuration	PARTITION_CONFIG	1	[179]	0h
Boot config protection	BOOT_CONFIG_PROT	1	[178]	0h
Boot bus Conditions	BOOT_BUS_CONDITIONS	1	[177]	0h
Reserved	–	1	[176]	-
High-density erase group definition	ERASE_GROUP_DEF	1	[175]	0h
Boot write protection status registers	BOOT_WP_STATUS	1	[174]	0h
Boot area write protection register	BOOT_WP	1	[173]	0h
Reserved	–	1	[172]	-
User area write protection register	USER_WP	1	[171]	0h
Reserved	–	1	[170]	-
FW configuration	FW_CONFIG	1	[169]	0h
RPMB Size	RPMB_SIZE_MULT	1	[168]	20h
Write reliability setting register	WR_REL_SET	1	[167]	00h
Write reliability parameter register	WR_REL_PARAM	1	[166]	15h
Start Sanitize operation	SANITIZE_START	1	[165]	0h
Manually start background operations	BKOPS_START	1	[164]	0h
Enable background operations handshake	BKOPS_EN	1	[163]	0h
H/W reset function	RST_n_FUNCTION	1	[162]	0h
HPI management	HPI_MGMT	1	[161]	0h
Partitioning Support	PARTITIONING_SUPPORT	1	[160]	7h



Name	Field	Size (Bytes)	CSD-slice	Value
Max Enhanced Area Size	MAX_ENH_SIZE_MULT	3	[159:157]	16GB: 624 32GB: 1245
Partitions attribute	PARTITIONS_ATTRIBUTE	1	[156]	0h
Partitioning Setting	PARTITION_SETTING_COMPLETED	1	[155]	0h
General Purpose Partition Size	GP_SIZE_MULT 4	3	[154:152]	0h
General Purpose Partition Size	GP_SIZE_MULT3	3	[151:149]	0h
General Purpose Partition Size	GP_SIZE_MULT2	3	[148:146]	0h
General Purpose Partition Size	GP_SIZE_MULT1	3	[145:143]	0h
Enhanced User Data Area Size	ENH_SIZE_MULT	3	[142:140]	0h
Enhanced User Data Start Address	ENH_START_ADDR	4	[139:136]	0h
Reserved	–	1	[135]	-
Bad Block Management mode	SEC_BAD_BLK_MGMNT	1	[134]	0h
Reserved		1	[133]	-
Package Case Temperature is controlled	TCASE_SUPPORT	1	[132]	0h
Periodic Wake-up	PERIODIC_WAKEUP	1	[131]	0h
Program CID/CSD in DDR mode support	PROGRAM_CID_CSD_DDR_SUPPORT	1	[130]	1h
Reserved	–	2	[129:128]	-
Vendor Specific Fields	VENDOR_SPECIFIC_FIELD	61	[127:64]	–
Native sector size	NATIVE_SECTOR_SIZE	1	[63]	0h
Sector size emulation	USE_NATIVE_SECTOR	1	[62]	0h
Sector size	DATA_SECTOR_SIZE	1	[61]	0h
1st initialization after disabling sector size emulation	INI_TIMEOUT_EMU	1	[60]	0h
Class 6 commands control	CLASS_6_CTRL	1	[59]	0h
Number of addressed group to be Released	DYNCAP_NEEDED	1	[58]	0h
Exception events control	EXCEPTION_EVENTS_CTRL	2	[57:56]	0h
Exception events status	EXCEPTION_EVENTS_STATUS	2	[55:54]	0h
Extended Partitions Attribute	EXT_PARTITIONS_ATTRIBUTE	2	[53:52]	0h
Context configuration	CONTEXT_CONF	15	[51:37]	0h



Name	Field	Size (Bytes)	CSD-slice	Value
Packed command status	PACKED_COMMAND_STATUS	1	[36]	0h
Packed command failure index	PACKED_FAILURE_INDEX	1	[35]	0h
Power Off Notification	POWER_OFF_NOTIFICATION	1	[34]	0h
Control to turn the Cache ON/OFF	CACHE_CTRL	1	[33]	0h
Flushing of the cache	FLUSH_CACHE	1	[32]	0h
Reserved		1	[31]	-
Mode config	MODE_CONFIG	1	[30:30]	0h
Mode operation codes	MODE_OPERATION_CODES	1	[29:29]	0h
Reserved	Reserved	2	[28:27]	-
FFU status	FFU_STATUS	1	[26:26]	0h
Pre loading data size	PRE_LOADING_DATA_SIZE	4	[25:22]	0h
Max pre loading data size	MAX_PRE_LOADING_DATA_SIZE	4	[21:18]	16GB: 009A2000h 32GB: 01356000h
Product state awareness enablement	PRODUCT_STATE_AWARENESS_ENABLEMENT	1	[17:17]	1h
Secure removal type	SECURE_REMOVAL_TYPE	1	[16:16]	39h
Command Queue Mode enable	CMQ_MODE_EN	1	[15:15]	0h
Reserved	Reserved	15	[14:0]	-

NOTES:

1. Reserved bits should read as “0.”
2. Obsolete values should be don’t care.
3. This field is 0 after power-on, H/W reset, or software reset, thus selecting the backward compatibility interface timing for the Device. If the host sets 1 to this field, the Device changes its timing to high-speed interface timing (see Section 10.6.1 of JESD84-B50). If the host sets value 2 the Device changes its timing to HS200 interface timing (see Section 10.8.1 of JESD84-B50), If the host sets HS_TIMING [3:0] to 0x3, the device changes its timing to HS400 interface timing (see 10.10).
4. It is set to ‘0’ (1-bit data bus) after power-up and can be changed by a SWITCH command.
5. * Changed by Firmware release note.

5.5. RCA Register

The writable 16-bit Relative Device Address (RCA) register carries the Device address assigned by the host during the Device identification. This address is used for the addressed host-device communication after the Device identification procedure. The default value of the RCA register is 0x0001. The value 0x0000 is reserved to set all Devices into the *Stand-by State* with CMD7.

5.6. DSR Register

The 16-bit driver stage register (DSR) is described in detail in Section 7.6 of the JEDEC Standard Specification No. JESD84-B51. It can be optionally used to improve the bus performance for extended operating conditions (depending on parameters like bus length, transfer rate, or number of Devices). The CSD register carries the information about the DSR register usage.

6. The eMMC bus

The eMMC bus has ten communication lines and three supply lines:

- CMD : Command is a bidirectional signal. The host and Device drivers are operating in two modes, open drain and push/pull.
- DAT0-7 : Data lines are bidirectional signals. Host and Device drivers are operating in push-pull mode
- CLK : The clock is a host to the device signal. CLK operates in push-pull mode
- Data Strobe: Data Strobe is a Device to host signal. Data Strobe operates in push-pull mode.

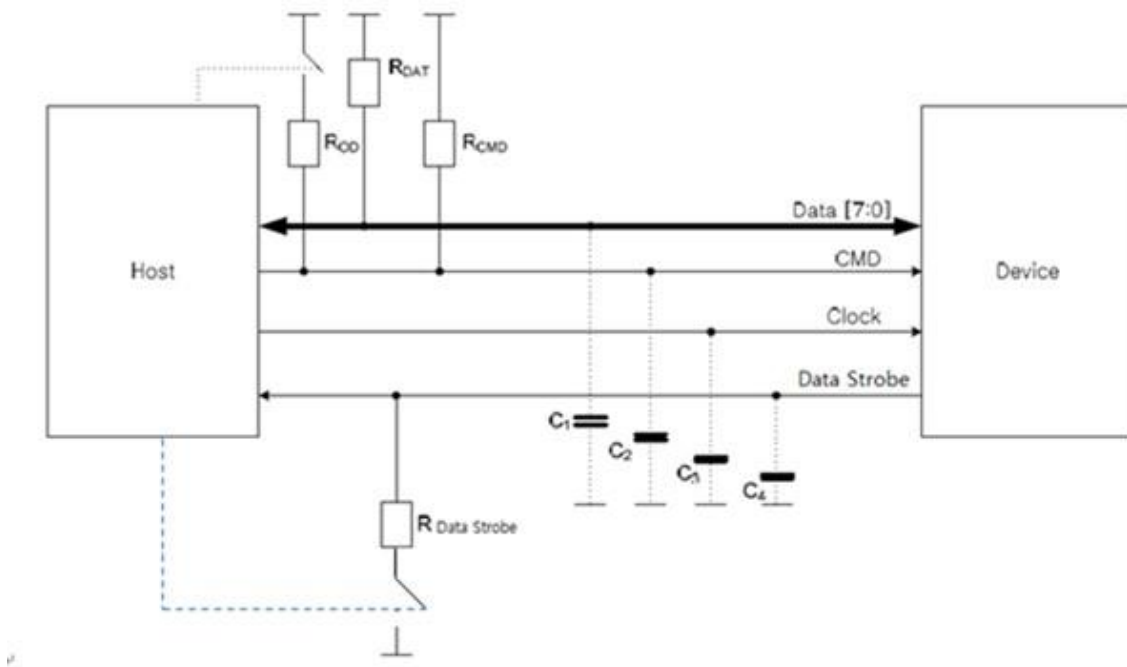


Figure 6-1 Bus Circuitry Diagram

The R_{OD} is switched on and off by the host synchronously to the open-drain and push-pull mode transitions. The host does not have to have open drain drivers but must recognize this mode to switch on the R_{OD} . R_{DAT} and R_{CMD} are pull-up resistors protecting the CMD and the DAT lines against bus floating devices when all device drivers are in a high-impedance mode.

A constant current source can replace the R_{OD} by achieving a better performance (constant slopes for the signal rising and falling edges). If the host does not allow the switchable R_{OD} implementation, a fixed R_{CMD} can be used). Consequently, the maximum operating frequency in the open drain mode has to be reduced if the used R_{CMD} value is higher than the minimal one given.

$R_{Data\ strobe}$ is a pull-down resistor used in HS400 devices.

6.1 Power-up

6.1.1 eMMC power-up

An eMMC bus power-up is handled locally in each device and the bus master. Figure 6-2 shows the power-up sequence and is followed by specific instructions regarding the power-up sequence. Refer to section 10.1 of the JEDEC Standard Specification No. JESD84-B51 for specific instructions regarding the power-up sequence.

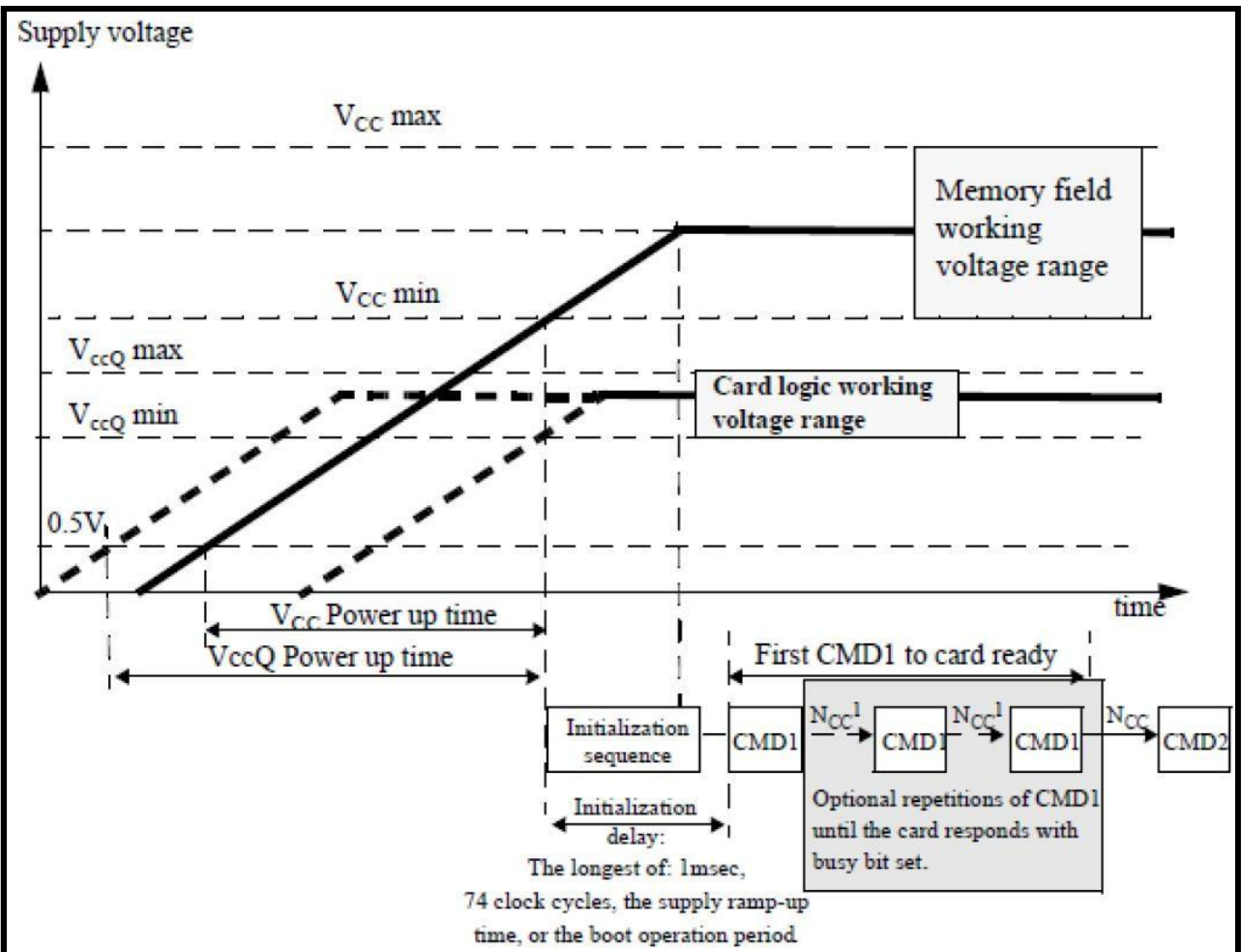


Figure 6-2 eMMC Power-up Diagram

6.1.2 eMMC Power Cycling

The master can execute any sequence of V_{CC} and V_{CCQ} power-up/power-down. However, the master must not issue any commands until V_{CC} and V_{CCQ} are stable within each operating voltage range. After the slave enters sleep mode, the master can power down V_{CC} to reduce power consumption. The slave must be ramped up to V_{CC} before the host issues CMD5 (SLEEP_AWAKE) to wake the slave unit. For more information about power cycling see Section 10.1.3 of the JEDEC Standard Specification No. JESD84-B51.

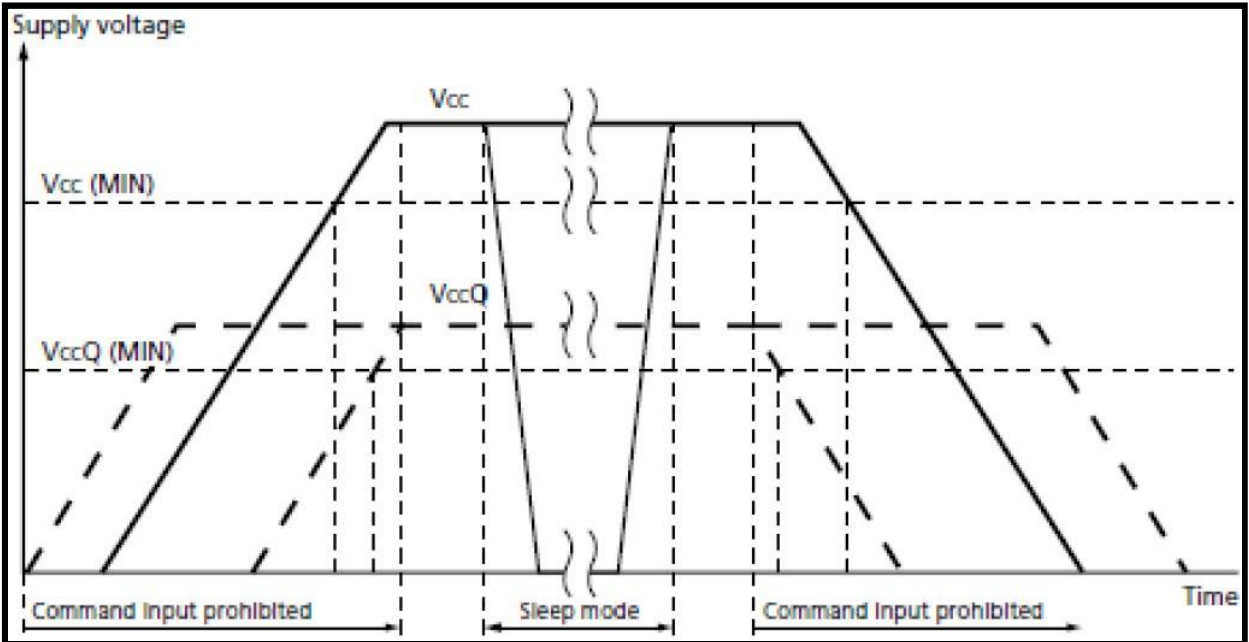


Figure 6-3 The eMMC Power Cycle



6.1.3 Power Cycle Requirements

As part of a power cycle, the host shall hold both the VCC and VCCQ voltage levels below 100mV for a minimum time of 100ns. If these requirements are not met as part of a power cycle operation, the device enters an indeterminate state. During VCC and VCCQ ramping, both power supplies can ramp at the same time or one after another. VCC and VCCQ shall be monotonically ramped up from 0V to operating voltage.

The device shall not be powered down during the eMMC busy period.

Table 6-1 VCC Power Loss Parameters

Symbol	Value
VCC_min(V)	2.7
VCC_rst(V)	2.6
VCC_PL_SLEW_RATE (min)	N/A
VCC_PL_SLEW_RATE (max)	8 mV/us

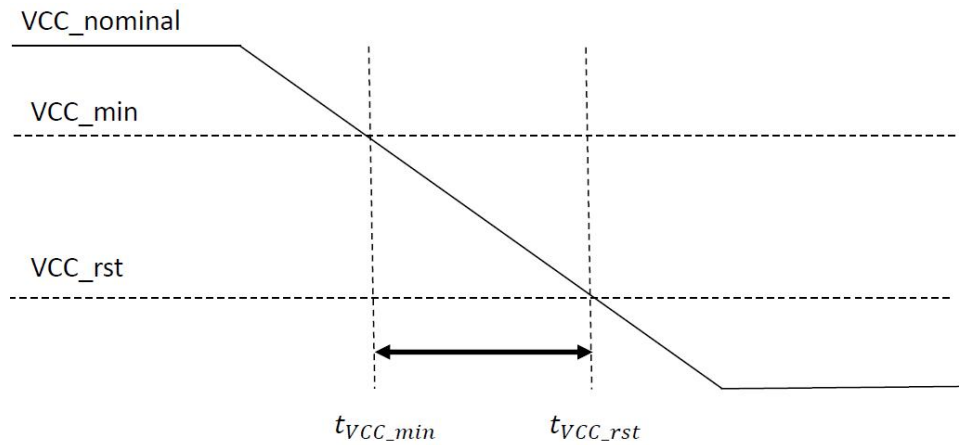


Figure 6-4 VCC Power Loss Diagram

Table 6-2 VCCQ Power Loss Parameters

Symbol	Value
VCCQ_min(V)	1.7
VCCQ_rst(V)	1.63

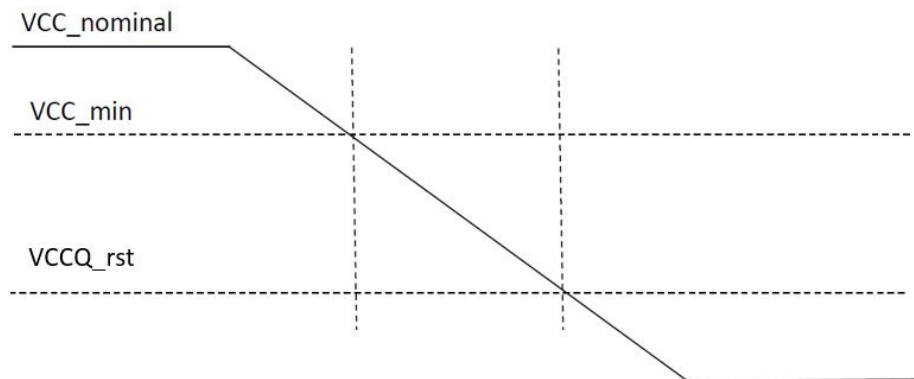


Figure 6-5 VCCQ Power Loss Diagram

Ensure the VCC/VCCQ power cycle drops below 100mV and supply power after 1ms.

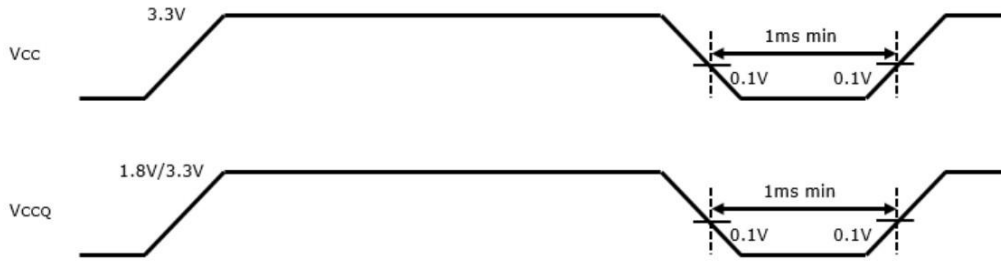


Figure 6-6 Power Cycle Requirement

6.2 Bus Operating Conditions

Table 6-3 General Operating Condition

Parameter	Symbol	Min	Max.	Unit	Remark
Peak voltage on all lines		-0.5	VCCQ + 0.5	V	
All Inputs					
Input Leakage Current (before initialization sequence ¹ and/or the internal pull-up resistors connected)		-100	100	μA	
Input Leakage Current (after initialization sequence and the internal pull-up resistors disconnected)		-2	2	μA	
All Outputs					
Output Leakage Current (before initialization sequence)		-100	100	μA	
Output Leakage Current (after initialization sequence) ²		-2	2	μA	
Note1 : Initialization sequence is defined in section 10.1 of the JEDEC Standard Specification No. JESD84-B51					
Note2 : DS (Data strobe) pin is excluded.					

6.2.1 Power supply: eMMC

In the *eMMC*, V_{CC} is used for the NAND flash device and its interface voltage; V_{CCQ} is for the controller and the MMC interface voltage as shown in Figure 6-7. The core regulator is optional and only required when internal core logic voltage is regulated from V_{CCQ}. A C_{REG} capacitor must be connected to the V_{DDi} terminal to stabilize regulator output on the system.

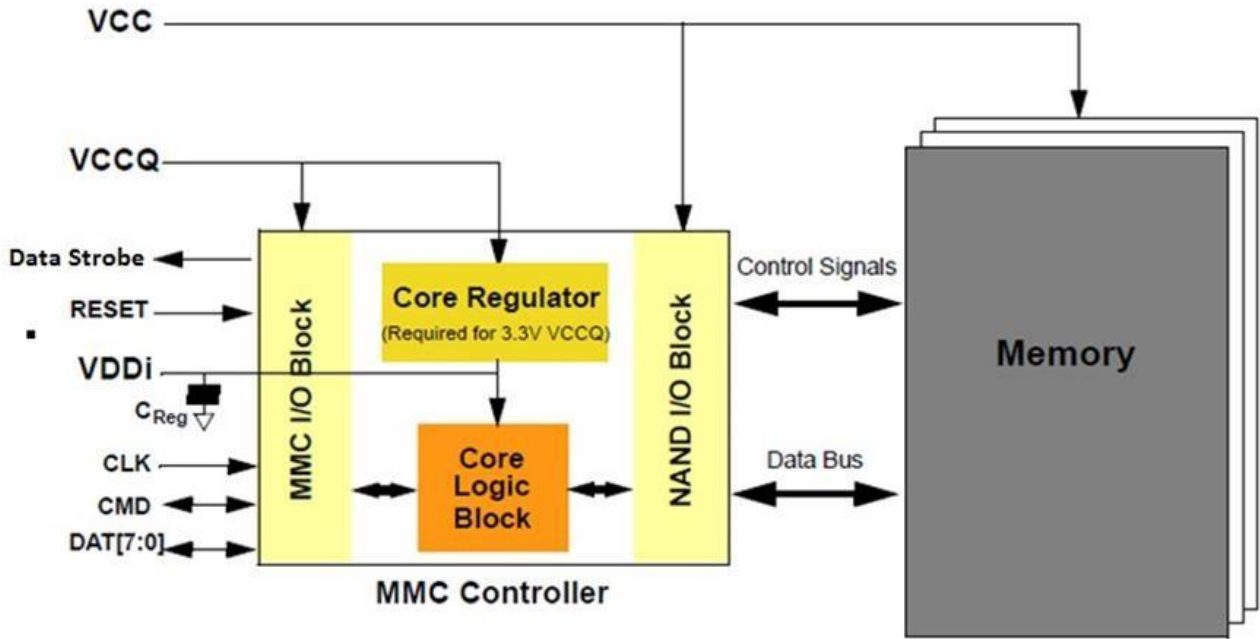


Figure 6-7 eMMC Internal Power Diagram



6.2.2 eMMC Power Supply Voltage

The eMMC supports one or more combinations of V_{CC} and V_{CCQ} as shown in Table 6-4. The V_{CCQ} must be defined as equal to or less than V_{CC} .

Table 6-4 eMMC Operating Voltage

Parameter	Symbol	MIN	MAX	Unit	Remarks
Supply voltage (NAND)	VCC	2.7	3.6	V	
Supply voltage (I/O)	VCCQ	2.7	3.6	V	
		1.7	1.95	V	
Supply power-up for 3.3V	tPRUH	0.036	35	ms	
Supply power-up for 1.8V	tPRUL	0.018	25	ms	

NOTE: Power noise on the supply voltage shall not exceed +/-3%.

AC noise Criteria: AC noise on the supply voltage shall not exceed $\pm 3\%$. 10 kHz to 800 MHz AC and DC noise together shall stay within the Min-Max range specified in this table

The eMMC must support at least one of the valid voltage configurations, and can optionally support all valid voltage configurations (see Table).

Table 6-5 eMMC Voltage Combinations

		V_{CCQ}	
		1.7V–1.95V	2.7V–3.6V ¹
Vcc	2.7V-3.6V	Valid	Valid

Note1 : V_{CCQ} (I/O) 3.3-volt range is not supported in HS200 /HS400 devices

6.2.3 Bus Signal Line Load

The total capacitance C_L of each line of the *eMMC* bus is the sum of the bus master capacitance C_{HOST} , the bus capacitance C_{BUS} itself, and the capacitance C_{DEVICE} of *eMMC* connected to this line:

$$C_L = C_{HOST} + C_{BUS} + C_{DEVICE}$$

The sum of the host and bus capacitances must be under 20pF.

Table 6-6 Signal Line Load

Parameter	Symbol	Min	Max	Typ	Unit	Remark
Pull-up resistance for CMD	R_{CMD}	4.7	50	10	Kohm	to prevent bus floating
Pull-up resistance for DAT0~7	R_{DAT}	10	50	10	Kohm	to prevent bus floating
Pull-up resistance for RST_n	R_{RST_n}	4.7	50	10	Kohm	It is not necessary to put pull-up resistance on RST_n (H/W rest) line if the host does not use H/W reset. (Extended CSD register [162] = 0b)
Bus signal line capacitance	C_L		30	30	pF	Single Device
Single Device capacitance	C_{BGA}		6	6	pF	
Maximum signal line inductance			16	16	nH	
Impedance on CLK / CMD / DAT0~7		45	55	50	ohm	Impedance match
Serial's resistance on CLK line	SR_{CLK}	0	47	0	ohm	
Serial's resistance on CMD / DAT0~7 line	SR_{CMD} $SR_{DAT0\sim7}$	0	47	0	ohm	
V_{CCQ} decoupling capacitor		2.2+0.1	4.7+0.22	4.7+0.1	μF	It should be located as close as possible to the balls defined to minimize connection parasitic
	CH1	1	2.2	1		CH1 is only for HS200. It should be placed adjacent to VCCQ-VSSQ balls (#K6 and #K4 accordingly, next to DAT[7..0] balls). It should be located as close as possible to the balls defined to minimize connection parasitism
V_{CC} capacitor value		2.2+0.1	4.7+0.22	4.7+0.22	μF	It should be located as close as possible to the balls defined to minimize connection parasitic
V_{DDi} capacitor value		1+0.1	4.7+0.1	2.2+0.1	μF	To stabilize regulator output to controller core logic. It should be located as close as possible to the balls defined to minimize connection parasitic

6.2.4 HS400 reference load

The circuit in Figure 6-8 shows the reference load used to define the HS400 Device Output Timings and overshoot / undershoot parameters.

The reference load is made up of the transmission line and the $C_{\text{REFERENCE}}$ capacitance.

The reference load is not intended to be a precise representation of the typical system environment nor a depiction of the actual load presented by a production tester.

System designers should use IBIS or other simulation tools to correlate the reference load to the system environment. Manufacturers should correlate to their production test conditions.

The delay time (t_d) of the transmission line has been introduced to make the reference load independent from the PCB technology and trace length.

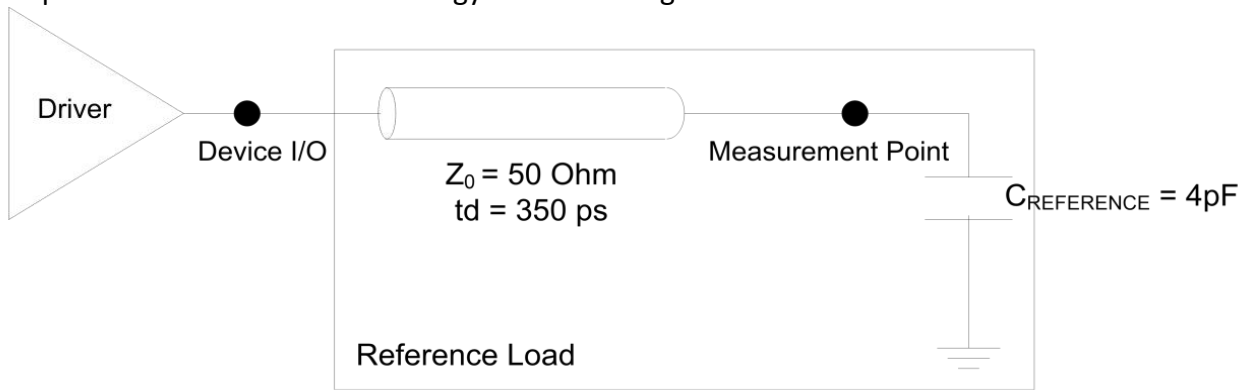


Figure 6-8 HS400 reference load

6.3 Bus Signal Levels

As the bus can be supplied with a variable supply voltage, all signal levels are related to the supply voltage.

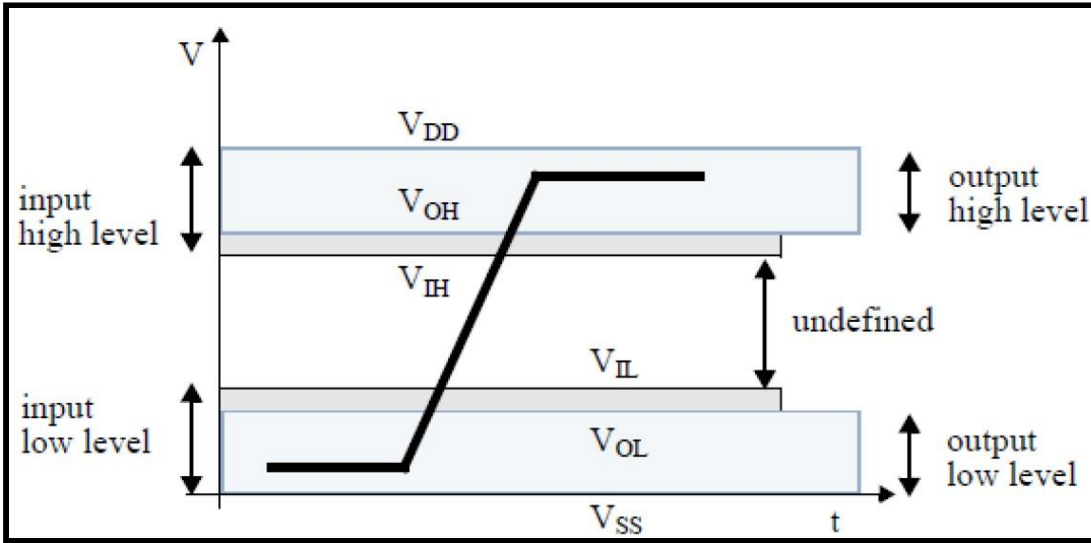


Figure 6-9 Bus Signal Levels

6.3.1 Open-drain Mode Bus Signal Level

Table 6-7 Open-drain Bus Signal Level

Parameter	Symbol	Min	Max.	Unit	Conditions
Output HIGH voltage	VOH	VDD – 0.2		V	IOH = -100 μ A
Output LOW voltage	VOL		0.3	V	IOL = 2 mA

The input levels are identical to the push-pull mode bus signal levels.

6.3.2 Push-pull mode bus signal level— eMMC

The device input and output voltages shall be within the following specified ranges for any V_{DD} of the allowed voltage range

For the 2.7V-3.6V V_{CCQ} range (compatible with JESD8C.01)

Table 6-8 Push-pull Signal Level—High-voltage eMMC

Parameter	Symbol	Min	Max.	Unit	Conditions
Output HIGH voltage	VOH	0.75 * VCCQ		V	IOH = -100 μ A @ V_{CCQ} min
Output LOW voltage	VOL		0.125 * VCCQ	V	IOL = 100 μ A @ V_{CCQ} min
Input HIGH voltage	VIH	0.625 * VCCQ	VCCQ + 0.3	V	
Input LOW voltage	VIL	VSS – 0.3	0.25 * VCCQ	V	

For the 1.70V – 1.95V V_{CCQ} range (: Compatible with EIA/JEDEC Standard “EIA/JESD8-7 Normal Range” as defined in the following table.

Table 6-9 Push-pull Signal Level—1.70 -1.95 V_{CCQ} Voltage Range

Parameter	Symbol	Min	Max.	Unit	Conditions
Output HIGH voltage	VOH	$V_{CCQ} - 0.45V$		V	IOH = -2mA
Output LOW voltage	VOL		0.45V	V	IOL = 2mA
Input HIGH voltage	VIH	$0.65 * V_{CCQ}^1$	$V_{CCQ} + 0.3$	V	
Input LOW voltage	VIL	$V_{SS} - 0.3$	$0.35 * V_{DD}^2$	V	

Note1 : $0.7 * V_{DD}$ for MMC™4.3 and older revisions.
 Note2 : $0.3 * V_{DD}$ for MMC™4.3 and older revisions.

6.3.3 Bus Operating Conditions for HS200 & HS400

The bus operating conditions for HS200 devices are the same as specified in sections 10.5.1 of JESD84- B51 through 10.5.2 of JESD84-B51. The only exception is that $V_{CCQ}=3.3v$ is not supported.

6.3.4 Device Output Driver Requirements for HS200 & HS400

Refer to section 10.5.4 of the JEDEC Standard Specification No. JESD84-B51.

6.4 Bus Timing

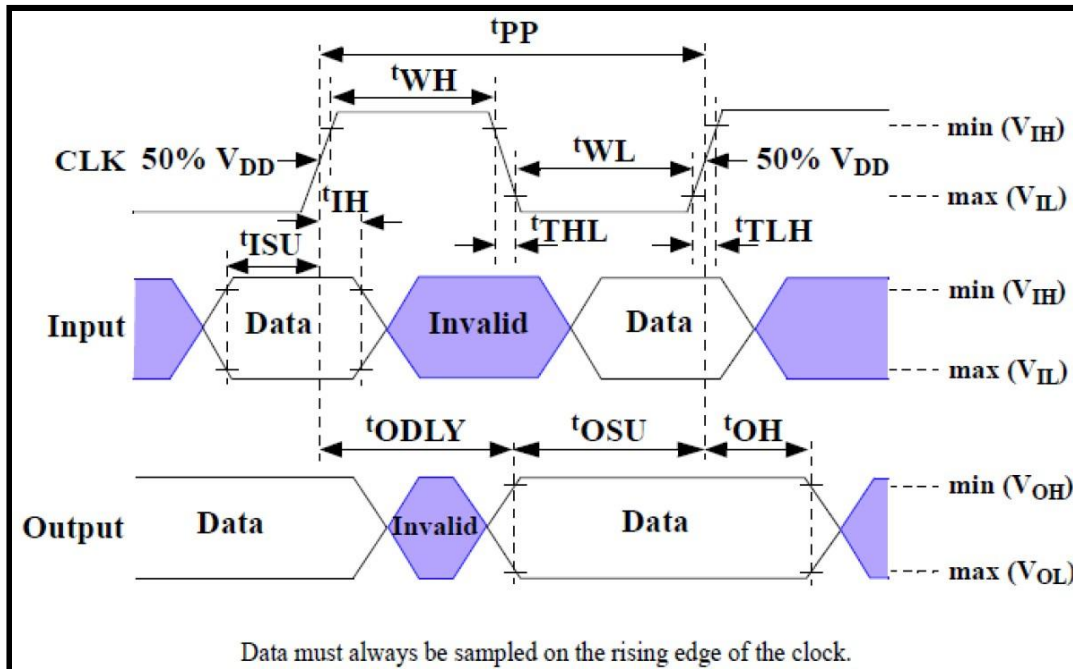


Figure 6-10 Timing Diagram



6.4.1 Device Interface Timings

Table 6-10 High-speed Device Interface Timing

Parameter	Symbol	Min	Max.	Unit	Remark
Clock CLK ¹					
Clock frequency Data Transfer Mode (PP) ²	fPP	0	52 ³	MHz	CL ≤ 30 pF Tolerance: +100KHz
Clock Frequency Identification Mode (OD)	fOD	0	400	kHz	Tolerance: +20KHz
Clock high time	tWH	6.5		ns	CL ≤ 30 pF
Clock low time	tWL	6.5		ns	CL ≤ 30 pF
Clock rise time ⁴	tTLH		3	ns	CL ≤ 30 pF
Clock fall time	tTHL		3	ns	CL ≤ 30 pF
Inputs CMD, DAT (referenced to CLK)					
Input set-up time	tISU	3		ns	CL ≤ 30 pF
Input hold time	tIH	3		ns	CL ≤ 30 pF
Outputs CMD, DAT (referenced to CLK)					
Output delay time during data transfer	tODLY		13.7	ns	CL ≤ 30 pF
Output hold time	tOH	2.5		ns	CL ≤ 30 pF
Signal rise time ⁵	tRISE		3	ns	CL ≤ 30 pF
Note1 : CLK timing is measured at 50% of VDD.					
Note2 : eMMC shall support the full frequency range from 0-26Mhz or 0-52MHz					
Note3 : Device can operate as high-speed Device interface timing at 26 MHz clock frequency.					
Note4 : CLK rise and fall times are measured by min (VIH) and max (VIL).					
Note5 : Inputs CMD DAT rise and fall times are measured by min (VIH) and max (VIL) and outputs CMD DAT rise and fall times are measured by min (VOH) and max (VOL). "					

Table 6-11 Backward-compatible Device Interface Timing

Parameter	Symbol	Min	Max.	Unit	Remark ¹
Clock CLK ²					
Clock frequency Data Transfer Mode (PP) ³	fPP	0	26	MHz	CL ≤ 30 pF
Clock frequency Identification Mode (OD)	fOD	0	400	kHz	
Clock high time	tWH	10			CL ≤ 30 pF
Clock low time	tWL	10		ns	CL ≤ 30 pF
Clock rise time ⁴	tTLH		10	ns	CL ≤ 30 pF
Clock fall time	tTHL		10	ns	CL ≤ 30 pF
Inputs CMD, DAT (referenced to CLK)					
Input set-up time	tISU	3		ns	CL ≤ 30 pF
Input hold time	tIH	3		ns	CL ≤ 30 pF
Outputs CMD, DAT (referenced to CLK)					
Output hold time ⁵	tOH	8.3		ns	CL ≤ 30 pF
Note1: The Device must always start with the backward-compatible interface timing. The timing mode can be switched to high-speed interface timing by the host sending the SWITCH command (CMD6) with the argument for high-speed interface selection.					
Note2: CLK timing is measured at 50% of VDD.					
Note3: For compatibility with Devices that support the v4.2 standard or earlier, the host should not use > 26 MHz before switching to high-speed interface timing.					
Note4: CLK rise and fall times are measured by min (VIH) and max (VIL).					
Note5: tOSU and tOH are defined as values from the clock's rising edge. However, there may be Devices or devices which utilize clock falling edge to output data in backward compatibility mode. Therefore, it is recommended for hosts either to set tWL value as long as possible within the range that will not go over tCK-tOH(min) in the system or to use a slow clock frequency, so that the host could have data set up margin for those devices. In this case, each device that utilizes a clock falling edge might show the correlation either between tWL and tOSU or between tCK and tOSU for the device in its datasheet as a note or its application notes.					

6.5 Bus Timing for DAT Signals During Dual Data Rate Operation

These timings apply to the DAT [7:0] signals only when the device is configured for dual data mode operation. In this dual data mode, the DAT signals operate synchronously on both the rising and the falling edges of CLK. The CMD signal still operates synchronously with the rising edge of CLK and therefore complies with the bus timing specified in section 10.5, therefore there is no timing change for the CMD signal.

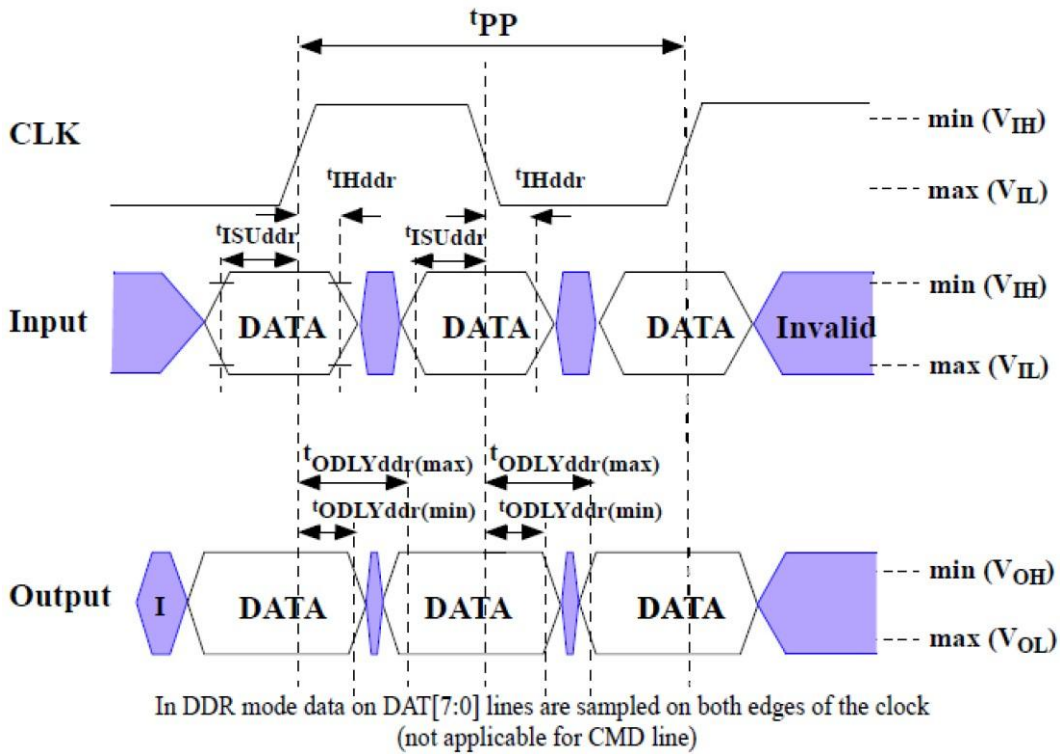


Figure 6-11 Timing Diagram: Data Input/Output in Dual Data Rate Mode

6.5.1 Dual Data Rate Interface Timings

Table 6-12 High-speed Dual Data Rate Interface Timing

Parameter	Symbol	Min	Max.	Unit	Remark
Input CLK ¹					
Clock duty cycle		45	55	%	Includes jitter, phase noise
Input DAT (referenced to CLK-DDR mode)					
Input set-up time	tISUddr	2.5		ns	CL ≤ 20 pF
Input hold time	tIHddr	2.5		ns	CL ≤ 20 pF
Output DAT (referenced to CLK-DDR mode)					
Output delay time during data transfer	tODLYddr	1.5	7	ns	CL ≤ 20 pF
Signal rise time (all signals) ²	tRISE		2	ns	CL ≤ 20 pF
Signal fall time (all signals)	tFALL		2	ns	CL ≤ 20 pF

Note1 : CLK timing is measured at 50% of VDD.
 Note2 : Inputs CMD, DAT rise and fall times are measured by min (V_{IH}) and max (V_{IL}), and outputs CMD, DAT rise and fall times are measured by min (V_{OH}) and max (V_{OL})

6.6 Bus Timing Specification in HS200 Mode

6.6.1 HS200 Clock Timing

Host CLK Timing in HS200 mode shall conform to the timing specified in Figure 6-12 and Table 6-13. CLK input shall satisfy the clock timing over all possible operation and environmental conditions. CLK input parameters should be measured while CMD and DAT lines are stable high or low, as close as possible to the Device.

The maximum frequency of HS200 is 200MHz. Hosts can use any frequency up to the maximum that HS200 mode allows.

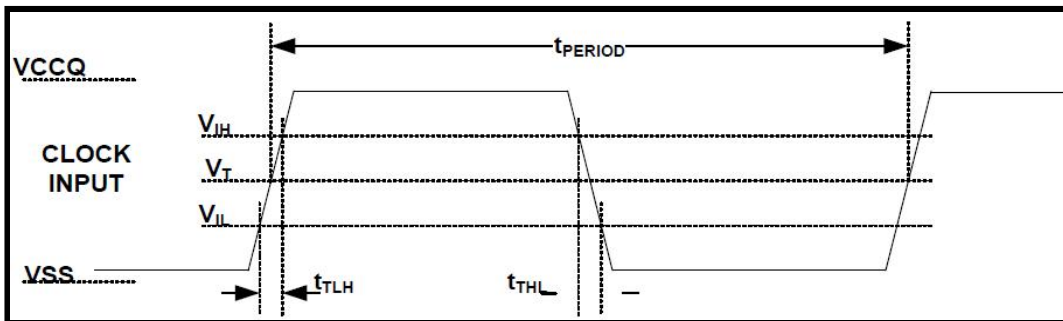


Figure 6-12 HS200 Clock Signal Timing

Note 1: V_{IH} denotes V_{IH} (min.) and V_{IL} denotes V_{IL} (max.).

Note 2: V_T = 50% of V_{CCO}, indicates clock reference point for timing measurements.

Table 6-13 HS200 Clock Signal Timing

Symbol	Min.	Max.	Unit	Remark
t _{PERIOD}	5	-	ns	200MHz (Max.), between rising edges
t _{TLH} , t _{THL}	-	0.2* t _{PERIOD}	ns	t _{TLH} , t _{THL} < 1ns (max.) at 200MHz, C _{BGA} =12pF, The absolute maximum value of t _{TLH} , t _{THL} is 10ns regardless of clock frequency.
Duty Cycle	30	70	%	

6.6.2 HS200 Device Input Timing

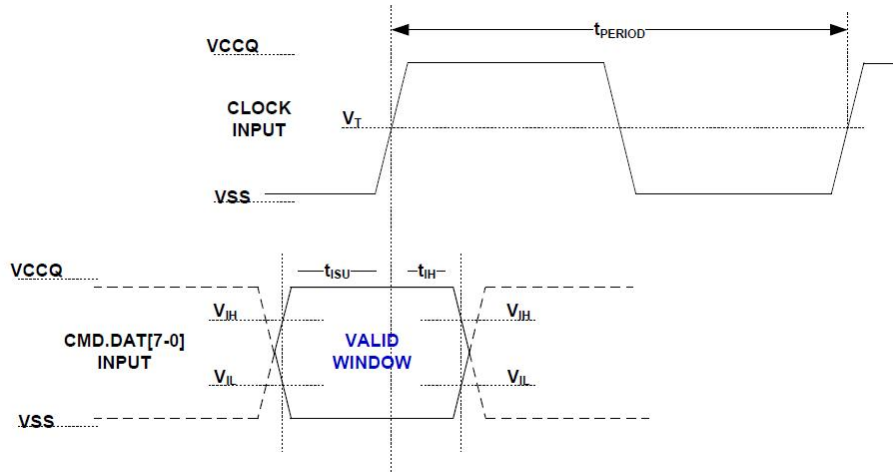


Figure 6-13 HS200 Device Input Timing

Note 1: t_{ISU} and t_{IH} are measured at V_{IL} (max.) and V_{IH} (min.).

Note 2: V_{IH} denotes V_{IH} (min.) and V_{IL} denotes V_{IL} (max.).

Table 6-14 HS200 Device Input Timing

Symbol	Min.	Max.	Unit	Remark
t_{ISU}	1.4	-	ns	$C_{BGA} \leq 6\text{pF}$
t_{IH}	0.8	-	ns	$C_{BGA} \leq 6\text{pF}$

6.6.3 HS200 Device Output Timing

t_{PH} parameter is defined to allow device output delay to be longer than t_{PERIOD} . After initialization, the t_{PH} may have a random phase relation to the clock. The Host is responsible for finding the optimal sampling point for the Device outputs while switching to the HS200 mode.

Figure 6-14 and Table 6-15 define Device output timing.

While setting the sampling point of data, a long-term drift, which mainly depends on temperature drift, should be considered. The temperature drift is expressed by ΔT_{PH} . Output valid data window (t_{VW}) is available regardless of the drift (ΔT_{PH}) but the position of the data window varies by the drift, as described in Figure 6-14.

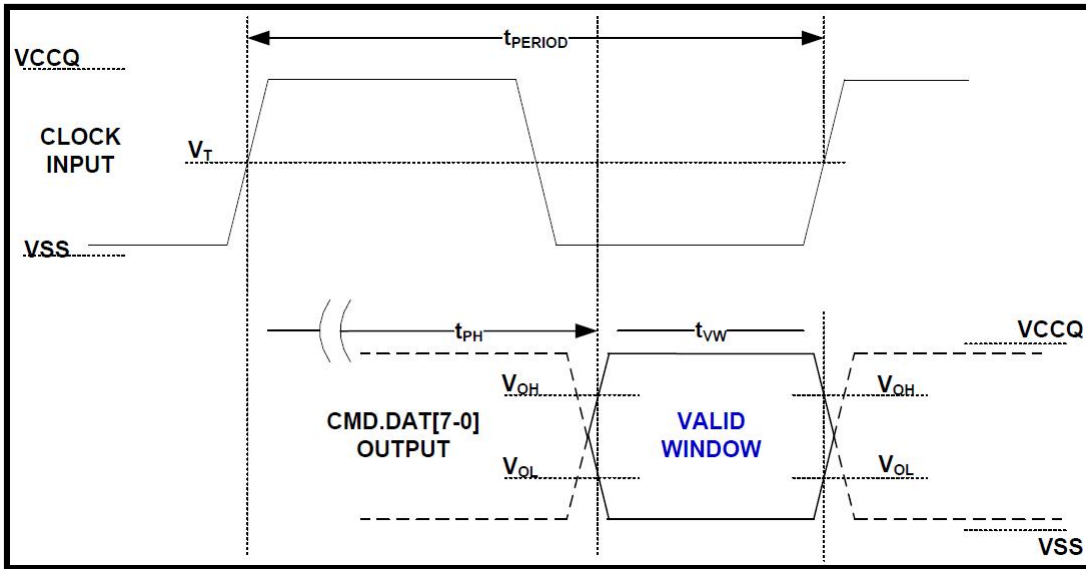


Figure 6-14 HS200 Device Output Timing

Note: V_{OH} denotes V_{OH} (min.) and V_{OL} denotes V_{OL} (max.).

Table 6-15 Output Timing

Symbol	Min.	Max.	Unit	Remark
t_{PH}	0	2	UI	Device output momentary phase from CLK input to CMD or DAT lines output. Does not include a long-term temperature drift.
ΔT_{PH}	-350 ($\Delta T = -20^\circ C$)	+1550 ($\Delta T = 90^\circ C$)	ps	Delay variation due to temperature change after tuning. The total allowable shift of output valid window (T_{VW}) from the last system Tuning procedure ΔT_{PH} is 2600ps for ΔT from $-25^\circ C$ to $125^\circ C$ during operation.
T_{VW}	0.575	-	UI	$t_{VW} = 2.88ns$ at 200MHz Using the test circuit in Figure 6-14 including skew among CMD and DAT lines created by the Device. The host path may add Signal integrity-induced noise, skews, etc. The expected T_{VW} at Host input is larger than 0.475UI.

Note : Unit Interval (UI) is one-bit nominal time. For example, UI=5ns at 200MHz.

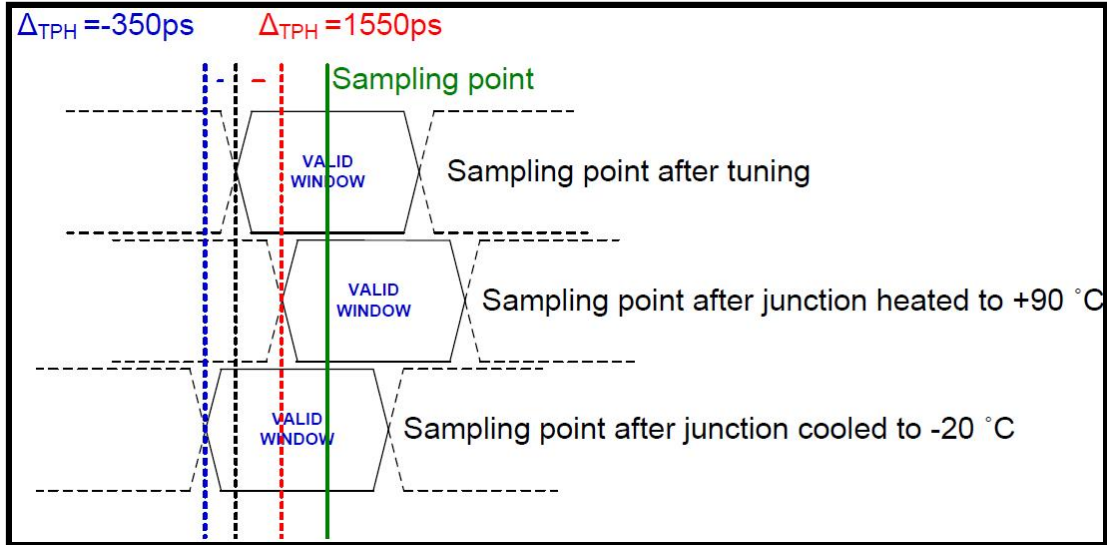


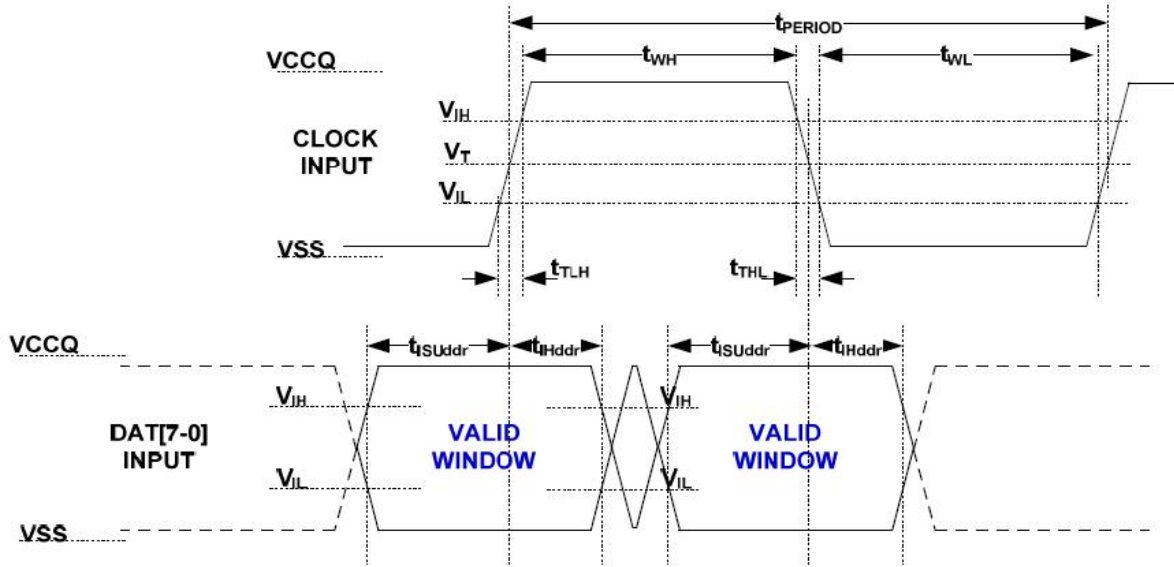
Figure 6-15 ΔT_{PH} consideration

Implementation Guide: Host should design to avoid sampling errors that may be caused by the Δ_{TPH} drift. It is recommended to perform tuning procedure while Device wakes up, after sleep. One simple way to overcome the Δ_{TPH} drift is by reduction of operating frequency.

6.7 Bus Timing Specification in HS400 Mode

6.7.1 HS400 Device Input Timing

The CMD input timing for HS400 mode is the same as the CMD input timing for HS200 mode. Figure 6-16 and Table 6-16 show Device input timing



Note1: t_{SU} and t_H are measured at $V_{IL(max)}$ and $V_{IH(min)}$.
 Note2: V_{IH} denote $V_{IH(min)}$ and V_{IL} denotes $V_{IL(max)}$.

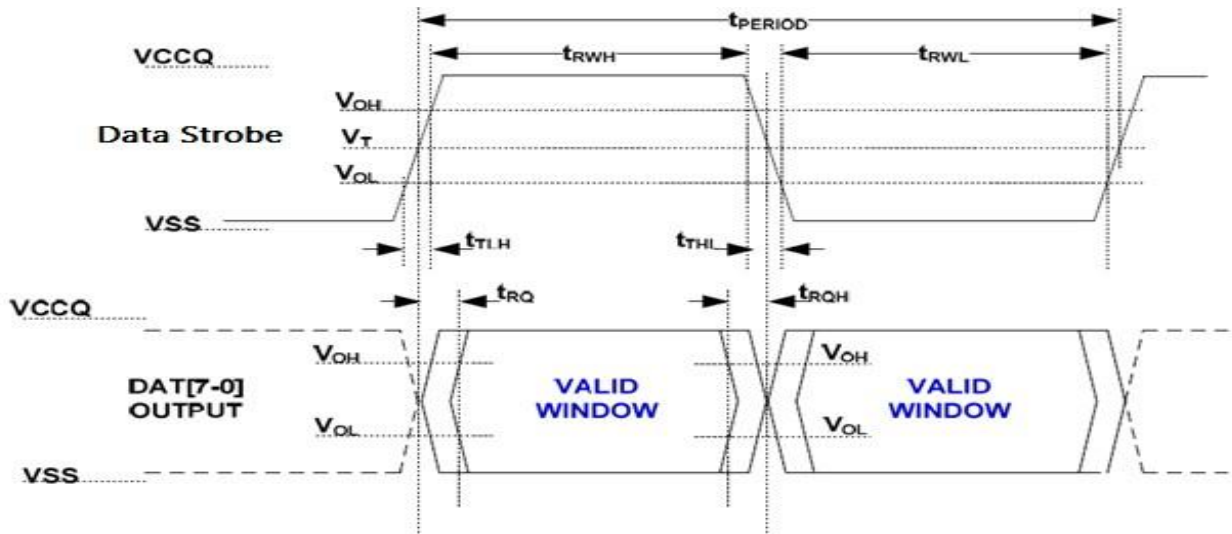
Figure 6-16 HS400 Device Data input timing

Table 6-16 HS400 Device input timing

Parameter	Symbol	Min	Max	Unit	Remark
Input CLK					
Cycle time data transfer mode	t_{PERIOD}	5			200MHz (Max), between rising edges With respect to V_T .
Slew rate	SR	1.125		V/ns	With respect to V_{IH}/V_{IL} .
Duty cycle distortion	t_{CKDCD}	0.0	0.3	ns	Allowable deviation from an ideal 50% duty cycle. With respect to V_T . Includes jitter, phase
Minimum pulse width	t_{CKMPW}	2.2		ns	With respect to V_T .
Input DAT (referenced to CLK)					
Input set-up time	t_{SUddr}	0.4		ns	$C_{Device} \leq 6pF$ With respect to V_{IH}/V_{IL} .
Input hold time	t_{Hddr}	0.4		ns	$C_{Device} \leq 6pF$ With respect to V_{IH}/V_{IL} .
Slew rate	SR	1.125		V/ns	With respect to V_{IH}/V_{IL} .

6.7.2 HS400 Device Output Timing

The Data Strobe is used to read data in HS400 mode. The Data Strobe is toggled only during data read or CRC status response.



Note: V_{OH} denotes $V_{OH(min)}$ and V_{OL} denotes $V_{OL(max)}$.

Note: $V_T = 50\%$ of V_{CCQ} , indicates clock reference point for timing measurements.

Figure 6-17 HS400 Device output timing

Table 6-17 HS400 Device Output timing

Parameter	Symbol	Min	Max	Unit	Remark
Data Strobe					
Cycle time data transfer mode	tPERIOD	5			200MHz (Max), between rising edges With respect to V_T
Slew rate	SR	1.125		V/ns	With respect to V_{OH}/V_{OL} and HS400 reference load
Duty cycle distortion	tDSDCD	0.0	0.2	ns	Allowable deviation from the input CLK duty cycle distortion (tCKDCD) With respect to V_T Includes jitter, phase noise
Minimum pulse width	tDSMPW	2.0		ns	With respect to V_T
Read pre-amble	tRPRE	0.4	-	tPERIOD	Max value is specified by manufacturer. Value up to infinite is valid
Read post-amble	tRPST	0.4	-	tPERIOD	Max value is specified by manufacturer. Value up to infinite is valid
Output DAT (referenced to Data Strobe)					
Slew rate	SR	1.125		V/ns	With respect to V_{OH}/V_{OL} and HS400 reference load

NOTE: Measured with HS400 reference load (6.2.4)

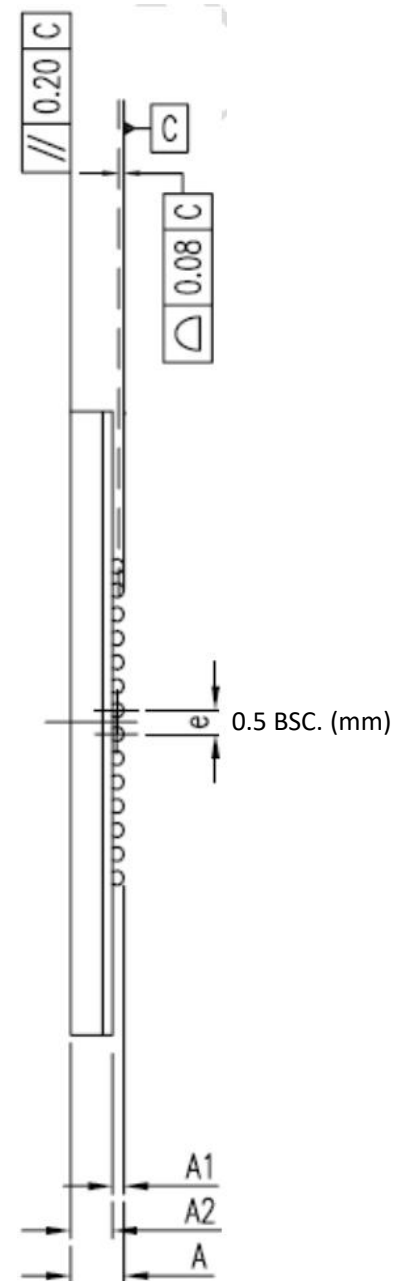
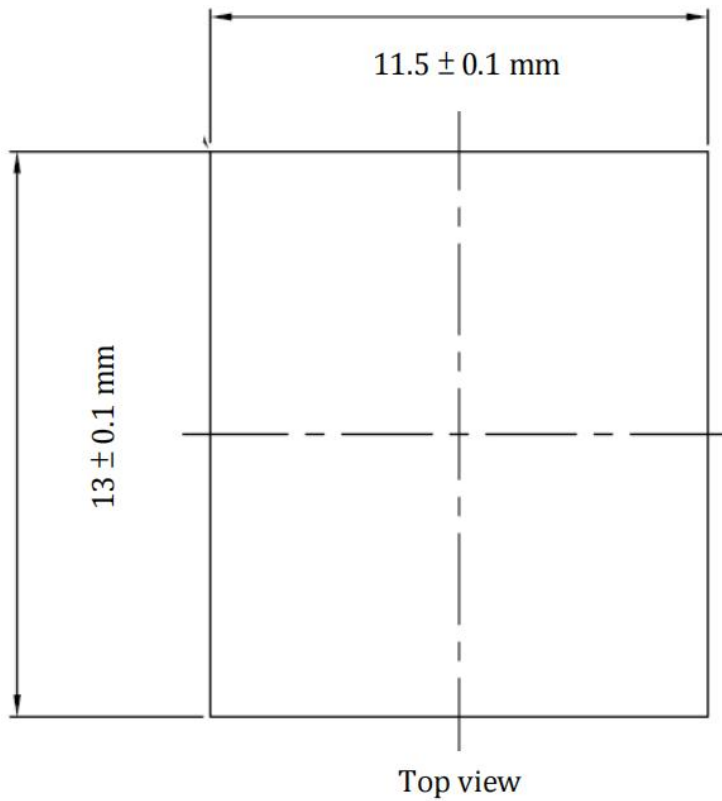


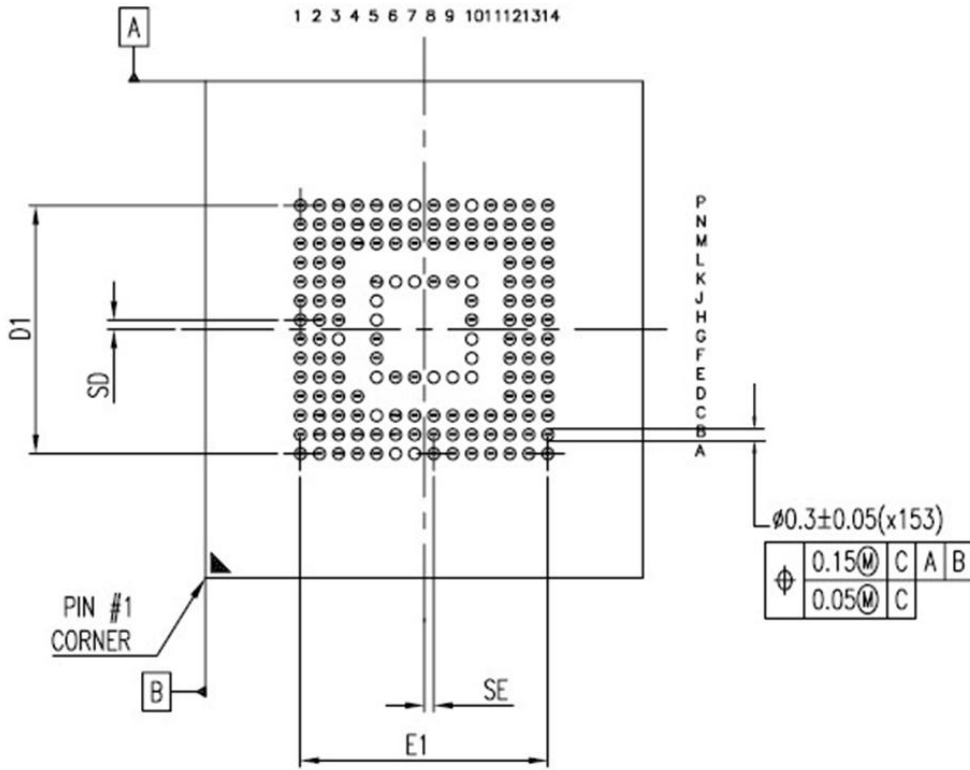
Table 6-18 HS400 Capacitance

Parameter	Symbol	Min	Type	Max	Unit	Remark
Pull-up resistance for CMD	RCMD	4.7		50	Kohm	
Pull-up resistance for DAT0-7	RDAT	10		50	Kohm	
Pull-down resistance for Data Strobe	RDS	10		50	Kohm	
Internal pull-up resistance DAT1-DAT7	R _{int}	10		150	Kohm	
Single Device capacitance	C _{Device}			6	pF	

7. Package connections

Device	Package Mechanical	A1 (MIN.)	A2	A (MAX.)
XT28EG16GA4YJECGA	11.5 x 13.0 x 1.0mm	0.16mm	0.69mm	1.0mm
XT28EG32GA4YJECGA	11.5 x 13.0 x 1.0mm			





BOTTOM VIEW

N	SE (MM)	SD (MM)	E1(MM)	D1(MM)	JEDEC(REF)
153	0.25 BSC.	0.25 BSC.	6.50 BSC.	6.50 BSC.	MO-276 BA



8. Ball Assignment (153 ball)

	1	2	3	4	5	6	7	8	9	10	11	12	13	14																														
A	NC	NC	DAT0	DAT1	DAT2	VSS	NC	NC	NC	NC	NC	NC	NC	NC	A																													
B	NC	DAT3	DAT4	DAT5	DAT6	DAT7	NC	NC	NC	NC	NC	NC	NC	NC	B																													
C	NC	VDDI	NC	VSSQ	NC	VCCQ	NC	NC	NC	NC	NC	NC	NC	NC	C																													
D	NC	NC	NC	NC								NC	NC	NC	D																													
E	NC	NC	NC	<table border="1"> <tr> <td>NC</td> <td>VCC</td> <td>VSS</td> <td>VSF1</td> <td>VSF2</td> <td>VSF3</td> </tr> <tr> <td>VCC</td> <td colspan="4"></td> <td>VSF4</td> </tr> <tr> <td>VSS</td> <td colspan="4"></td> <td>VSF5</td> </tr> <tr> <td>DS</td> <td colspan="4"></td> <td>VSS</td> </tr> <tr> <td>VSS</td> <td colspan="4"></td> <td>VCC</td> </tr> <tr> <td>RST_n</td> <td>NC</td> <td>NC</td> <td>VSS</td> <td>VCC</td> <td>VSF6</td> </tr> </table>	NC	VCC	VSS	VSF1	VSF2	VSF3	VCC					VSF4	VSS					VSF5	DS					VSS	VSS					VCC	RST_n	NC	NC	VSS	VCC	VSF6	NC	NC	NC	E
NC	VCC	VSS	VSF1		VSF2	VSF3																																						
VCC					VSF4																																							
VSS					VSF5																																							
DS					VSS																																							
VSS					VCC																																							
RST_n	NC	NC	VSS		VCC	VSF6																																						
F	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	F																														
G	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	G																														
H	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	H																														
J	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	J																														
K	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	NC	K																														
L	NC	NC	NC	NC								NC	NC	NC	L																													
M	NC	NC	NC	VCCQ	CMD	CLK	NC	NC	NC	NC	NC	NC	NC	M																														
N	NC	VSSQ	NC	VCCQ	VSSQ	NC	NC	NC	NC	NC	NC	NC	NC	N																														
P	NC	NC	VCCQ	VSSQ	VCCQ	VSSQ	NC	NC	NC	VSF7	NC	NC	NC	P																														
	1	2	3	4	5	6	7	8	9	10	11	12	13	14																														

Figure 8-1 153 ball assignment



9. Temperature

Parameter	Grade	Rating	Unit
Operating temperature (Tcase)	Commercial Grade	-25 ~ + 85	°C
Storage temperature (Tcase)	Commercial Grade	-40 ~ + 85	°C

10. Ordering Information

The ordering part number is formed by a valid combination of the following.

Ordering Information	XT28EG16GA4YJECGA XT28EG32GA4YJECGA
Company Prefix	XT = XTX
Product family	28E = eMMC
Voltage (NAND Core + NAND IO & eMMC Controller)	G: 3.3V + 1.8V Q: 2.5V + 1.8V U: 3.3V + 1.2V V: 2.5V + 1.2V
Product Density	16G = 16GB 32G = 32GB
Internal Information	A4YJ
Package Type	E = 153-ball FBGA, 11.5x13x1mm
Temperature & Grade	C: -25C to + 85C (WT) I: -40C to +85C (IT) D: -40C to +85C (Auto AEC-Q100 grade3) H: -40C to +105C (Auto AEC-Q100 grade2)
Green Code	G = Green/RoHS/Reach
Product Carrier	A = Tray



11. Portfolio

Part Number	Flash Type	Grade	Package	AEC-Q100	Density
XT28EG16GA4 YJECGA	TLC	Commercial	153Ball	N/A	16GB
XT28EG32GA4 YJECGA					32GB



12. Product Warranty Policy

In the event the Product does not conform to the specification within XTX's agreed warranty period and such conformity is solely attributable to XTX's cause, XTX agrees at its discretion to replace or repair the nonconforming Product. Notwithstanding the foregoing, the aforementioned warranty shall exclude the conformity arising from, about, or associated with:

- (1) Alteration, modification, improper use, misuse, or excessive use of the Product;
- (2) Failure to comply with XTX's instructions;
- (3) XTX's compliance with the customer (including the customer's suppliers, subcontractors, or downstream customers) indicated instructions, technologies, designs, specifications, materials, components, and parts;
- (4) Combination of the Product with other materials, components, parts, goods, hardware, firmware, or software not developed by XTX; or
- (5) Other errors or failures not solely attributable to XTX's cause (including without limitation, normal wear or tear, manufacturing or assembly wastage, improper operation, virus, unauthorized maintenance or repair).

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